

14-Bit, 80 MSPS/105 MSPS/125 MSPS, 1.8 V Analog-to-Digital Converter

AD9246

FEATURES

1.8 V analog supply operation 1.8 V to 3.3 V output supply

SNR = 71.7 dBc (72.7 dBFS) to 70 MHz input

SFDR = 85 dBc to 70 MHz input Low power: 395 mW @ 125 MSPS

Differential input with 650 MHz bandwidth

On-chip voltage reference and sample-and-hold amplifier

 $DNL = \pm 0.4 LSB$

Flexible analog input: 1 V p-p to 2 V p-p range

Offset binary, Gray code, or twos complement data format

Clock duty cycle stabilizer

Data output clock Serial port control

Built-in selectable digital test pattern generation

Programmable clock and data alignment

APPLICATIONS

Ultrasound equipment IF sampling in communications receivers IS-95, CDMA-One, IMT-2000 **Battery-powered instruments Hand-held scopemeters** Low cost digital oscilloscopes

GENERAL DESCRIPTION

The AD9246 is a monolithic, single 1.8 V supply, 14-bit, 80 MSPS/ 105 MSPS/125 MSPS analog-to-digital converter (ADC), featuring a high performance sample-and-hold amplifier (SHA) and on-chip voltage reference. The product uses a multistage differential pipeline architecture with output error correction logic to provide 14-bit accuracy at 125 MSPS data rates and guarantees no missing codes over the full operating temperature range.

The wide bandwidth, truly differential SHA allows a variety of user-selectable input ranges and offsets, including single-ended applications. It is suitable for multiplexed systems that switch full-scale voltage levels in successive channels and for sampling single-channel inputs at frequencies well beyond the Nyquist rate. Combined with power and cost savings over previously available ADCs, the AD9246 is suitable for applications in communications, imaging, and medical ultrasound.

A differential clock input controls all internal conversion cycles. A duty cycle stabilizer (DCS) compensates for wide variations in the clock duty cycle while maintaining excellent overall ADC performance.

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FUNCTIONAL BLOCK DIAGRAM

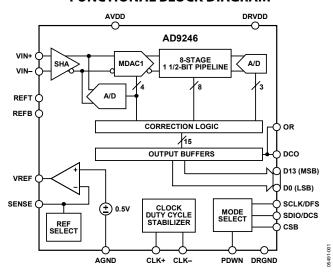


Figure 1.

The digital output data is presented in offset binary, Gray code, or twos complement formats. A data output clock (DCO) is provided to ensure proper latch timing with receiving logic.

The AD9246 is available in a 48-lead LFCSP_VQ and is specified over the industrial temperature range (-40° C to $+85^{\circ}$ C).

PRODUCT HIGHLIGHTS

- The AD9246 operates from a single 1.8 V power supply and features a separate digital output driver supply to accommodate 1.8 V to 3.3 V logic families.
- The patented SHA input maintains excellent performance for input frequencies up to 225 MHz.
- The clock DCS maintains overall ADC performance over a wide range of clock pulse widths.
- A standard serial port interface supports various product features and functions, such as data formatting (offset binary, twos complement, or Gray coding), enabling the clock DCS, power-down, and voltage reference mode.
- The AD9246 is pin-compatible with the AD9233, allowing a simple migration from 12 bits to 14 bits.

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AD9246* Product Page Quick Links

Last Content Update: 08/30/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

· AD9246 Evaluation Board

Documentation <a>□

Application Notes

- AN-1142: Techniques for High Speed ADC PCB Layout
- AN-1408: Using the AD8376 VGA to Drive Wide Bandwidth ADCs for High IF AC-Coupled Applications
- AN-282: Fundamentals of Sampled Data Systems
- AN-345: Grounding for Low-and-High-Frequency Circuits
- AN-501: Aperture Uncertainty and ADC System Performance
- AN-715: A First Approach to IBIS Models: What They Are and How They Are Generated
- AN-737: How ADIsimADC Models an ADC
- AN-741: Little Known Characteristics of Phase Noise
- AN-742: Frequency Domain Response of Switched-Capacitor ADCs
- AN-756: Sampled Systems and the Effects of Clock Phase Noise and Jitter
- AN-807: Multicarrier WCDMA Feasibility
- AN-808: Multicarrier CDMA2000 Feasibility
- AN-812: MicroController-Based Serial Port Interface (SPI) Boot Circuit
- AN-827: A Resonant Approach to Interfacing Amplifiers to Switched-Capacitor ADCs
- AN-835: Understanding High Speed ADC Testing and Evaluation
- AN-851: A WiMax Double Downconversion IF Sampling Receiver Design
- AN-878: High Speed ADC SPI Control Software
- AN-905: Visual Analog Converter Evaluation Tool Version 1.0 User Manual
- AN-935: Designing an ADC Transformer-Coupled Front End

Data Sheet

 AD9246: 14-Bit, 80 MSPS/105 MSPS/125 MSPS, 1.8 V Analog-to-Digital Converter Data Sheet

Tools and Simulations

- · Visual Analog
- AD9246 IBIS Models

Reference Designs 🖵

• CN0051

Reference Materials

Analog Dialogue

 Ask The Application Engineer 36, Wideband A/D Converter Front-End Design Considerations II: Amplifieror Transformer Drive for the ADC?

Technical Articles

- Improve The Design Of Your Passive Wideband ADC Front-End Network
- Matching An ADC To A Transformer
- MS-2210: Designing Power Supplies for High Speed ADC

Design Resources

- · AD9246 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

Discussions 🖳

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TABLE OF CONTENTS

Features	Timing	22
Applications	Serial Port Interface (SPI)	23
General Description	Configuration Using the SPI	23
Functional Block Diagram	Hardware Interface	23
Product Highlights	Configuration Without the SPI	23
Revision History	Memory Map	24
Specifications	Reading the Memory Map Register Table	24
DC Specifications	Memory Map Register Table	25
AC Specifications	Layout Considerations	27
Digital Specifications6	Power and Ground Recommendations	27
Switching Specifications	CML	27
Timing Diagram7	RBIAS	27
Absolute Maximum Ratings 8	Reference Decoupling	27
Thermal Resistance	Evaluation Board	28
ESD Caution 8	Power Supplies	28
Pin Configuration and Function Descriptions9	Input Signals	28
Equivalent Circuits	Output Signals	28
Typical Performance Characteristics	Default Operation and Jumper Selection Settings	29
Theory of Operation	Alternative Clock Configurations	29
Analog Input Considerations15	Alternative Analog Input Drive Configuration	29
Voltage Reference	Schematics	31
Clock Input Considerations	Evaluation Board Layouts	36
Jitter Considerations	Bill of Materials	39
Power Dissipation and Standby Mode20	Outline Dimensions	42
Digital Outputs21	Ordering Guide	42

REVISION HISTORY

8/06—Rev. 0 to Rev. A	
Added 80 MSPS	Universa
Changes to Features	1
Deleted Figures 19, 20, 22, 23	11
Deleted Figures 24, 25, 27 to 29	
Deleted Figures 31, 34	13
Deleted Figures 37, 38, 40, 41	14
Deleted Figure 46	

Changes to Figure 41 17 Changes to Figure 46 19 Inserted Figure 54 21 Added Data Clock Output (DCO) Section 22 Changes to Table 15 25 Changes to Table 16 35 Changes to the Ordering Guide 42	Deleted Figure 52	16
Inserted Figure 54	Changes to Figure 41	17
Added Data Clock Output (DCO) Section	Changes to Figure 46	19
Changes to Table 15	Inserted Figure 54	21
Changes to Table 16	Added Data Clock Output (DCO) Section	22
e	Changes to Table 15	25
Changes to the Ordering Guide42	Changes to Table 16	39
	Changes to the Ordering Guide	42

4/06—Revision 0: Initial Version

SPECIFICATIONS

DC SPECIFICATIONS

AVDD = 1.8 V; DRVDD = 2.5 V, maximum sample rate, 2 V p-p differential input, 1.0 V internal reference; AIN = -1.0 dBFS, DCS enabled, unless otherwise noted.

Table 1.

		AD9246BCPZ-80		AD9246BCPZ-105			AD9246BCPZ-125				
Parameter	Temp	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
RESOLUTION	Full	14			14			14			Bits
ACCURACY											
No Missing Codes	Full	(Guarante	ed		Guarante	eed		Guarante	ed	
Offset Error	Full		±0.3	±0.5		±0.3	±0.8		±0.3	±0.8	% FSR
Gain Error	Full		±0.6	±4.7		±0.6	±5.0		±0.6	±4.2	% FSR
Differential Nonlinearity (DNL) ¹	Full			±1.0			±1.0			±1.0	LSB
	25°C		±0.4			±0.4			±0.4		LSB
Integral Nonlinearity (INL) ¹	Full			±5.0			±5.0			±5.0	LSB
	25°C		±1.5			±1.3			±1.5		LSB
TEMPERATURE DRIFT											
Offset Error	Full		±15			±15			±15		ppm/°C
Gain Error	Full		±95			±95			±95		ppm/°C
INTERNAL VOLTAGE REFERENCE											
Output Voltage Error (1 V Mode)	Full		±5	±20		±5	±35		±5	±35	mV
Load Regulation @ 1.0 mA	Full		7			7			7		mV
INPUT REFERRED NOISE											
VREF = 1.0 V	25°C		1.3			1.3			1.3		LSB rms
ANALOG INPUT											
Input Span, VREF = 1.0 V	Full		2			2			2		V p-p
Input Capacitance ²	Full		8			8			8		pF
REFERENCE INPUT RESISTANCE	Full		6			6			6		kΩ
POWER SUPPLIES											
Supply Voltage											
AVDD	Full	1.7	1.8	1.9	1.7	1.8	1.9	1.7	1.8	1.9	V
DRVDD	Full	1.7	2.5	3.6	1.7	2.5	3.6	1.7	2.5	3.6	V
Supply Current											
IAVDD ¹	Full		138	155		178	194		220	236	mA
$IDRVDD^{1}$ (DRVDD = 1.8 V)	Full		7			9			11		mA
$IDRVDD^{1}$ (DRVDD = 3.3 V)	Full		12			16			19		mA
POWER CONSUMPTION											
DC Input	Full		248	279		320	350		395	425	mW
Sine Wave Input ¹ (DRVDD = 1.8 V)	Full		261			337			415		mW
Sine Wave Input ¹ (DRVDD = 3.3 V)	Full		288			373			458		mW
Standby Power ³	Full		40			40			40		mW
Power-Down Power	Full		1.8			1.8			1.8		mW

 $^{^{1}}$ Measured with a low input frequency, full-scale sine wave, with approximately 5 pF loading on each output bit.

² Input capacitance refers to the effective capacitance between one differential input pin and AGND. Refer to Figure 4 for the equivalent analog input structure.

³ Standby power is measured with a dc input, the CLK pin inactive (set to AVDD or AGND).

AC SPECIFICATIONS

AVDD = 1.8 V; DRVDD = 2.5 V, maximum sample rate, 2 V p-p differential input, 1.0 V internal reference; AIN = -1.0 dBFS, DCS enabled, unless otherwise noted.

Table 2.

	AD9246BCPZ-80		Z-80	AD9246BCPZ-105			AD9246BCPZ-125				
Parameter ¹	Temp	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
SIGNAL-TO-NOISE-RATIO (SNR)											
$f_{IN} = 2.4 \text{ MHz}$	25°C		71.9			71.9			71.9		dBc
$f_{IN} = 70 \text{ MHz}$	25°C		71.9			71.9			71.7		dBc
	Full	70.8			69.5			69.5			dBc
$f_{IN} = 100 \text{ MHz}$	25°C		71.6			71.6			71.6		dBc
$f_{IN} = 170 \text{ MHz}$	25°C		70.9			70.9			70.8		dBc
SIGNAL-TO-NOISE AND DISTORTION (SINAD)											
$f_{IN} = 2.4 \text{ MHz}$	25°C		71.1			71.1			71.1		dBc
$f_{IN} = 70 \text{ MHz}$	25°C		71.5			70.8			70.6		dBc
	Full	70.4			68.5			68.5			dBc
$f_{IN} = 100 \text{ MHz}$	25°C		70.6			70.6			70.6		dBc
f _{IN} = 170 MHz	25°C		69.9			69.9			69.8		dBc
EFFECTIVE NUMBER OF BITS (ENOB)	-										
f _{IN} = 2.4 MHz	25°C		11.7			11.7			11.7		Bits
f _{IN} = 70 MHz	25°C		11.6			11.6			11.6		Bits
f _{IN} = 100 MHz	25°C		11.6			11.6			11.6		Bits
f _{IN} = 170 MHz	25°C		11.5			11.5			11.5		Bits
WORST SECOND OR THIRD HARMONIC											
f _{IN} = 2.4 MHz	25°C		-90			-90			-90		dBc
$f_{IN} = 70 \text{ MHz}$	25°C		-85			-85			-85		dBc
	Full			-76			-73			-73	dBc
$f_{IN} = 100 \text{ MHz}$	25°C		-85			-85			-85		dBc
f _{IN} = 170 MHz	25°C		-83.5			-83.5			- 83		dBc
SPURIOUS-FREE DYNAMIC RANGE (SFDR)											
f _{IN} = 2.4 MHz	25°C		90			90			90		dBc
$f_{IN} = 70 \text{ MHz}$	25°C		85			85			85		dBc
	Full	76			73			73			dBc
$f_{IN} = 100 \text{ MHz}$	25°C	, ,	85		7.5	85		'	85		dBc
f _{IN} = 170 MHz	25°C		83.5			83.5			83		dBc
WORST OTHER HARMONIC OR SPUR											
$f_{IN} = 2.4 \text{ MHz}$	25°C		-90			-90			-90		dBc
$f_{\rm IN} = 2.4 \text{MHz}$	25°C		-90			-90			-90		dBc
- III	Full		,,	-85		,,	-80		,,	-80	dBc
$f_{IN} = 100 \text{ MHz}$	25°C		-90			-90	* =		-90	50	dBc
f _{IN} = 170 MHz	25°C		-90			-90			-90		dBc
TWO-TONE SFDR			,,,								
f _{IN} = 29 MHz (-7 dBFS), 32 MHz (-7 dBFS)	25°C		87			87			85		dBc
f _{IN} = 169 MHz (-7 dBFS), 172 MHz (-7 dBFS)	25°C		83			83			84		dBc
ANALOG INPUT BANDWIDTH	25°C		650			650			650		MHz

 $^{^{1}\,\}text{See AN-835}, \textit{Understanding High Speed ADC Testing and Evaluation}, for a complete set of definitions.$

DIGITAL SPECIFICATIONS

AVDD = 1.8 V; DRVDD = 2.5 V, maximum sample rate, 2 V p-p differential input, 1.0 V internal reference; AIN = -1.0 dBFS, DCS enabled, unless otherwise noted.

Table 3.

	AD9	AD9246BCPZ-80/105/125				
Parameter	Temp	Min	Тур	Max	Unit	
DIFFERENTIAL CLOCK INPUTS (CLK+, CLK-)						
Logic Compliance		C	MOS/LVDS	/LVPECL		
Internal Common-Mode Bias	Full		1.2		V	
Differential Input Voltage	Full	0.2		6	V p-p	
Input Voltage Range	Full	AVDD - 0.3		AVDD + 1.6	V	
Input Common-Mode Range	Full	1.1		AVDD	V	
High Level Input Voltage (V _H)	Full	1.2		3.6	V	
Low Level Input Voltage (V _{IL})	Full	0		0.8	V	
High Level Input Current (I _{IH})	Full	-10		+10	μΑ	
Low Level Input Current (IIL)	Full	-10		+10	μA	
Input Resistance	Full	8	10	12	kΩ	
Input Capacitance	Full		4		pF	
LOGIC INPUTS (SCLK/DFS, OEB, PWDN)					'	
High Level Input Voltage (V _{IH})	Full	1.2		3.6	V	
Low Level Input Voltage (V _I L)	Full	0		0.8	V	
High Level Input Current (I _{IH})	Full	-50		–75	μΑ	
Low Level Input Current (I _{IL})	Full	-10		+10	μΑ	
Input Resistance	Full		30		kΩ	
Input Capacitance	Full		2		pF	
LOGIC INPUTS (CSB)	- I un				Ρ'	
High Level Input Voltage (V _H)	Full	1.2		3.6	V	
Low Level Input Voltage (V_{IL})	Full	0		0.8	v	
High Level Input Current (I _{IH})	Full	_10		+10	μΑ	
Low Level Input Current (I _{IL})	Full	+40		+135	μΑ	
Input Resistance	Full		26		kΩ	
Input Capacitance	Full		2		pF	
LOGIC INPUTS (SDIO/DCS)	Tun				Pi	
High Level Input Voltage (V _H)	Full	1.2		DRVDD + 0.3	V	
Low Level Input Voltage (V_{IL})	Full	0		0.8	V	
High Level Input Current (I _{IH})	Full	_10		+10	μA	
Low Level Input Current (IIL)	Full	+40		+130	μΑ	
Input Resistance	Full	140	26	1130	kΩ	
Input Resistance Input Capacitance	Full		5		pF	
DIGITAL OUTPUTS	i un				Pi	
DRVDD = 3.3 V						
High Level Output Voltage (VoH, IoH = 50 μA)	Full	3.29			V	
	Full				V	
High Level Output Voltage (V _{OH} , I _{OH} = 0.5 mA)	Full	3.25		0.2	V	
Low Level Output Voltage (Vo., lo. = 1.6 mA)				0.2 0.05	V	
Low Level Output Voltage (V_{OL} , $I_{OL} = 50 \mu A$) DRVDD = 1.8 V	Full			0.05	V	
	FII	1.70			V	
High Level Output Voltage (V _{OH} , I _{OH} = 50 μA)	Full	1.79				
High Level Output Voltage (V_{OH} , $I_{OH} = 0.5$ mA)	Full	1.75		0.2	V	
Low Level Output Voltage (Vol., lol = 1.6 mA)	Full			0.2	V	
Low Level Output Voltage (V_{OL} , $I_{OL} = 50 \mu A$)	Full			0.05	V	

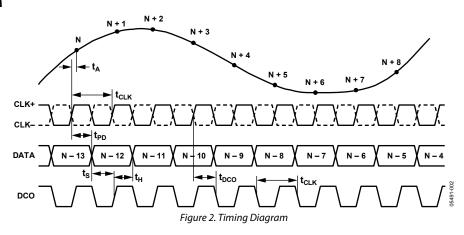
SWITCHING SPECIFICATIONS

AVDD = 1.8 V, DRVDD = 2.5 V, unless otherwise noted.

Table 4.

		AD9	9246BC	PZ-80	AD9	246BCP	Z-105	AD9	246BCF	Z-125	
Parameter ¹	Temp	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
CLOCK INPUT PARAMETERS											
Conversion Rate, DCS Enabled	Full	20		80	20		105	20		125	MSPS
Conversion Rate, DCS Disabled	Full	10		80	10		105	10		125	MSPS
CLK Period	Full	12.5			9.5			8			ns
CLK Pulse Width High, DCS Enabled	Full	3.75	6.25	8.75	2.85	4.75	6.65	2.4	4	5.6	ns
CLK Pulse Width High, DCS Disabled	Full	5.63	6.25	6.88	4.28	4.75	5.23	3.6	4	4.4	ns
DATA OUTPUT PARAMETERS											
Data Propagation Delay (tpd) ²	Full	3.1	3.9	4.8	3.1	3.9	4.8	3.1	3.9	4.8	ns
DCO Propagation Delay (t _{DCO})	Full		4.4			4.4			4.4		ns
Setup Time (ts)	Full	4.9	5.7		3.4	4.3		2.6	3.5		ns
Hold Time (t _H)	Full	5.9	6.8		4.4	5.3		3.7	4.5		ns
Pipeline Delay (Latency)	Full		12			12			12		cycles
Aperture Delay (t _A)	Full		0.8			8.0			0.8		ns
Aperture Uncertainty (Jitter, t _J)	Full		0.1			0.1			0.1		ps rms
Wake-Up Time ³	Full		350			350			350		μs
OUT-OF-RANGE RECOVERY TIME	Full		2			2			3		Cycles
SERIAL PORT INTERFACE⁴											
SCLK Period (t _{CLK})	Full	40			40			40			ns
SCLK Pulse Width High Time (t _{HI})	Full	16			16			16			ns
SCLK Pulse Width Low Time (t _{LO})	Full	16			16			16			ns
SDIO to SCLK Setup Time (t _{DS})	Full	5			5			5			ns
SDIO to SCLK Hold Time (t_{DH})	Full	2			2			2			ns
CSB to SCLK Setup Time (ts)	Full	5			5			5			ns
CSB to SCLK Hold Time (t _H)	Full	2			2			2			ns

TIMING DIAGRAM



¹ See AN-835, *Understanding High Speed ADC Testing and Evaluation*, for a complete set of definitions. ² Output propagation delay is measured from CLK 50% transition to DATA 50% transition, with 5 pF load.

³ Wake-up time is dependent on the value of the decoupling capacitors, values shown with 0.1 μF capacitor across REFT and REFB.

⁴ See Figure 57 and the Serial Port Interface (SPI) section.

ABSOLUTE MAXIMUM RATINGS

Table 5.

ELECTRICAL AVDD to AGND DRVDD to DGND AGND to DGND AGND to DGND AVDD to DGND AVDD to DRVDD DO through D13 to DGND O.3 V to +2.0 V DO through D13 to DGND O.3 V to +2.0 V DO to DGND O.3 V to P2.0 V DO to DGND O.3 V to DRVDD + 0.3 V OR to DGND CLK+ to AGND CLK+ to AGND VIN+ to AGND VIN+ to AGND VREF to AGND SENSE to AGND REFT to AGND SENSE to AGND DO3 V to AVDD + 0.2 V REFB to AGND REFB to AGND DO3 V to AVDD + 0.2 V REFB to AGND CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.2 V CLK+ to AGND CO3 V to AVDD + 0.3 V CO3 V to AVDD + 0.2 V CO3 V to AV	Tuble 3.	T .
AVDD to AGND DRVDD to DGND AGND to DGND AGND to DGND AVDD to DRVDD D0 through D13 to DGND DCO to DGND OR to DGND CLK+ to AGND CLK- to AGND VIN+ to AGND VIN+ to AGND SENSE to AGND REFT to AGND CSB to AGND CCSB to AGND CCSB to AGND CCSD to +3.9 V CCSD to +3.0	Parameter	Rating
DRVDD to DGND AGND to DGND AGND to DGND AVDD to DRVDD D0 through D13 to DGND DCO to DGND OR to DGND CLK+ to AGND VIN+ to AGND VIN- to AGND SENSE to AGND REFT to AGND CSB to AGND CSB to AGND CCSB to AGND CCSD to AGNO CCST TO AGNO CCSD TO	ELECTRICAL	
AGND to DGND AVDD to DRVDD D0 through D13 to DGND DCO to DGND OR to DGND CLK+ to AGND CLK- to AGND VIN+ to AGND VIN- to AGND SENSE to AGND SDIO/DCS to DGND CSB to AGND CSB to AGND CSB to AGND CSB to AGND CCK/DFS to AGND CC	AVDD to AGND	-0.3 V to +2.0 V
AVDD to DRVDD D0 through D13 to DGND DCO to DGND OR to DGND CLK+ to AGND CLK- to AGND VIN+ to AGND VIN- to AGND SENSE to AGND REFT to AGND SDIO/DCS to DGND CSB to AGND CCB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature Range CCB to AGNC CCB to AGNC CCCB TORVDD + 0.3 V CCCB to AGNC CCCB TORVDD + 0.3 V CCCB	DRVDD to DGND	−0.3 V to +3.9 V
D0 through D13 to DGND DCO to DGND OR to DGND CLK+ to AGND CLK− to AGND VIN+ to AGND VIN− to AGND SENSE to AGND SENSE to AGND CDBOD REFT to AGND SDIO/DCS to DGND CCB to AGND CCB to +3.9 V CCB to +3.0 V CCB to +3.9 V CCB to +3.0 V CCB to +3.9 V CCB to +3.0 V CCB to +3.0 V CCB to +3.0 V CCB to +3.0	AGND to DGND	−0.3 V to +0.3 V
DCO to DGND OR to DGND OR to DGND CLK+ to AGND CLK- to AGND VIN+ to AGND VIN+ to AGND VREF to AGND SENSE to AGND SDIO/DCS to DGND PDWN to AGND CSB to AGND SCLK/DFS to AGND ORED CSB to AGND SCLK/DFS to AGND ORED CSB to AGND	AVDD to DRVDD	−3.9 V to +2.0 V
OR to DGND CLK+ to AGND CLK- to AGND VIN+ to AGND VIN+ to AGND VREF to AGND SENSE to AGND REFT to AGND SDIO/DCS to DGND CSB to AGND CSB to	D0 through D13 to DGND	-0.3 V to DRVDD + 0.3 V
CLK+ to AGND CLK- to AGND CLK- to AGND VIN+ to AGND VIN+ to AGND VIN- to AGND VREF to AGND SENSE to AGND REFT to AGND SIDIO/DCS to DGND CSB to AGND CS	DCO to DGND	-0.3 V to DRVDD + 0.3 V
CLK- to AGND -0.3 V to +3.9 V VIN+ to AGND -0.3 V to AVDD + 0.2 V VIN- to AGND -0.3 V to AVDD + 0.2 V VREF to AGND -0.3 V to AVDD + 0.2 V SENSE to AGND -0.3 V to AVDD + 0.2 V REFT to AGND -0.3 V to AVDD + 0.2 V REFB to AGND -0.3 V to AVDD + 0.2 V SDIO/DCS to DGND -0.3 V to DRVDD + 0.3 V PDWN to AGND -0.3 V to +3.9 V CSB to AGND -0.3 V to +3.9 V SCLK/DFS to AGND -0.3 V to +3.9 V OEB to AGND -0.3 V to +3.9 V ENVIRONMENTAL Storage Temperature Range -65°C to +125°C Operating Temperature Range -40°C to +85°C Lead Temperature +300°C	OR to DGND	-0.3 V to DRVDD + 0.3 V
VIN+ to AGND −0.3 V to AVDD + 0.2 V VIN- to AGND −0.3 V to AVDD + 0.2 V VREF to AGND −0.3 V to AVDD + 0.2 V SENSE to AGND −0.3 V to AVDD + 0.2 V REFT to AGND −0.3 V to AVDD + 0.2 V REFB to AGND −0.3 V to AVDD + 0.2 V SDIO/DCS to DGND −0.3 V to DRVDD + 0.3 V PDWN to AGND −0.3 V to +3.9 V CSB to AGND −0.3 V to +3.9 V SCLK/DFS to AGND −0.3 V to +3.9 V OEB to AGND −0.3 V to +3.9 V ENVIRONMENTAL Storage Temperature Range −65°C to +125°C Operating Temperature Range −60°C to +85°C Lead Temperature +300°C	CLK+ to AGND	−0.3 V to +3.9 V
VIN− to AGND −0.3 V to AVDD + 0.2 V VREF to AGND −0.3 V to AVDD + 0.2 V SENSE to AGND −0.3 V to AVDD + 0.2 V REFT to AGND −0.3 V to AVDD + 0.2 V REFB to AGND −0.3 V to AVDD + 0.2 V SDIO/DCS to DGND −0.3 V to DRVDD + 0.3 V PDWN to AGND −0.3 V to +3.9 V CSB to AGND −0.3 V to +3.9 V SCLK/DFS to AGND −0.3 V to +3.9 V OEB to AGND −0.3 V to +3.9 V ENVIRONMENTAL Storage Temperature Range −65°C to +125°C Operating Temperature Range −40°C to +85°C Lead Temperature +300°C	CLK- to AGND	−0.3 V to +3.9 V
VREF to AGND -0.3 V to AVDD + 0.2 V SENSE to AGND -0.3 V to AVDD + 0.2 V REFT to AGND -0.3 V to AVDD + 0.2 V REFB to AGND -0.3 V to AVDD + 0.2 V SDIO/DCS to DGND -0.3 V to DRVDD + 0.3 V PDWN to AGND -0.3 V to +3.9 V CSB to AGND -0.3 V to +3.9 V SCLK/DFS to AGND -0.3 V to +3.9 V OEB to AGND -0.3 V to +3.9 V ENVIRONMENTAL Storage Temperature Range Operating Temperature Range -65°C to +125°C Lead Temperature -40°C to +85°C +300°C	VIN+ to AGND	−0.3 V to AVDD + 0.2 V
SENSE to AGND -0.3 V to AVDD + 0.2 V REFT to AGND -0.3 V to AVDD + 0.2 V REFB to AGND -0.3 V to AVDD + 0.2 V SDIO/DCS to DGND -0.3 V to DRVDD + 0.3 V PDWN to AGND -0.3 V to +3.9 V CSB to AGND -0.3 V to +3.9 V SCLK/DFS to AGND -0.3 V to +3.9 V OBB to AGND -0.3 V to +3.9 V ENVIRONMENTAL -0.3 V to +3.9 V Storage Temperature Range -65°C to +125°C Operating Temperature Range -40°C to +85°C Lead Temperature +300°C	VIN- to AGND	-0.3 V to AVDD + 0.2 V
REFT to AGND REFB to AGND SDIO/DCS to DGND PDWN to AGND CSB to AGND SCLK/DFS to AGND OBB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature (Soldering 10 Sec) -0.3 V to AVDD + 0.2 V -0.3 V to DRVDD + 0.3 V -0.3 V to +3.9 V -65°C to +125°C -40°C to +85°C +300°C	VREF to AGND	-0.3 V to AVDD + 0.2 V
REFB to AGND SDIO/DCS to DGND PDWN to AGND CSB to AGND SCLK/DFS to AGND OEB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature (Soldering 10 Sec) -0.3 V to AVDD + 0.2 V -0.3 V to DRVDD + 0.3 V -0.3 V to +3.9 V -0.3 V to +3.9 V -0.3 V to +3.9 V -65°C to +125°C -40°C to +85°C +300°C	SENSE to AGND	−0.3 V to AVDD + 0.2 V
SDIO/DCS to DGND PDWN to AGND CSB to AGND SCLK/DFS to AGND OEB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -0.3 V to +3.9 V -0.3 V to +3.9 V -0.3 V to +3.9 V -65°C to +125°C -40°C to +85°C +300°C	REFT to AGND	−0.3 V to AVDD + 0.2 V
PDWN to AGND CSB to AGND SCLK/DFS to AGND OEB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -0.3 V to +3.9 V -0.4 V to +3.9 V -0.5°C to +125°C -40°C to +85°C +300°C	REFB to AGND	-0.3 V to AVDD + 0.2 V
CSB to AGND SCLK/DFS to AGND OEB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -0.3 V to +3.9 V -0.4 V to +3.9 V -0.5 °C to +125 °C -40 °C to +85 °C +300 °C	SDIO/DCS to DGND	-0.3 V to DRVDD + 0.3 V
SCLK/DFS to AGND OEB to AGND -0.3 V to +3.9 V -0.3 V to +3.9 V ENVIRONMENTAL Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -0.3 V to +3.9 V	PDWN to AGND	−0.3 V to +3.9 V
OEB to AGND ENVIRONMENTAL Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -0.3 V to +3.9 V -65°C to +125°C -40°C to +85°C +300°C	CSB to AGND	−0.3 V to +3.9 V
ENVIRONMENTAL Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -65°C to +125°C -40°C to +85°C +300°C	SCLK/DFS to AGND	−0.3 V to +3.9 V
Storage Temperature Range Operating Temperature Range Lead Temperature (Soldering 10 Sec) -65°C to +125°C -40°C to +85°C +300°C	OEB to AGND	-0.3 V to +3.9 V
Operating Temperature Range Lead Temperature (Soldering 10 Sec) -40°C to +85°C +300°C	ENVIRONMENTAL	
Lead Temperature +300°C (Soldering 10 Sec)	Storage Temperature Range	-65°C to +125°C
(Soldering 10 Sec)	Operating Temperature Range	-40°C to +85°C
	•	+300°C
	(Soldering 10 Sec)	
Junction Temperature +150°C	Junction Temperature	+150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

The exposed paddle must be soldered to the ground plane for the LFCSP_VQ package. Soldering the exposed paddle to the customer board increases the reliability of the solder joints, maximizing the thermal capability of the package.

Table 6. Thermal Resistance

Package Type	θја	Ө лс	Unit
48-lead LFCSP_VQ (CP-48-3)	26.4	2.4	°C/W

Typical θ_{JA} and θ_{JC} are specified for a 4-layer board in still air. Airflow increases heat dissipation effectively reducing θ_{JA} . In addition, metal in direct contact with the package leads from metal traces, and through holes, ground, and power planes, reduces the θ_{JA} .

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

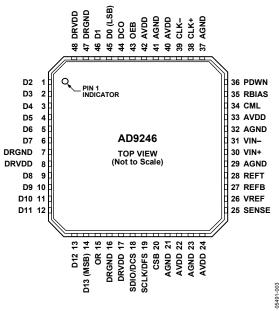


Figure 3. Pin Configuration

Table 7. Pin Function Description

Pin No.	Mnemonic	Description
0, 21, 23, 29, 32, 37, 41	AGND	Analog Ground. (Pin 0 is the exposed thermal pad on the bottom of the package.)
45, 46, 1 to 6, 9 to 14	D0 (LSB) to D13 (MSB)	Data Output Bits.
7, 16, 47	DRGND	Digital Output Ground.
8, 17, 48	DRVDD	Digital Output Driver Supply (1.8 V to 3.3 V).
15	OR	Out-of-Range Indicator.
18	SDIO/DCS	Serial Port Interface (SPI)® Data Input/Output (Serial Port Mode); Duty Cycle Stabilizer Select (External Pin Mode). See Table 10.
19	SCLK/DFS	Serial Port Interface Clock (Serial Port Mode); Data Format Select Pin (External Pin Mode).
20	CSB	Serial Port Interface Chip Select (Active Low). See Table 10.
22, 24, 33, 40, 42	AVDD	Analog Power Supply.
25	SENSE	Reference Mode Selection. See Table 9.
26	VREF	Voltage Reference Input/Output.
27	REFB	Differential Reference (–).
28	REFT	Differential Reference (+).
30	VIN+	Analog Input Pin (+).
31	VIN-	Analog Input Pin (–).
34	CML	Common-Mode Level Bias Output.
35	RBIAS	External Bias Resistor Connection. A 10 k Ω resistor must be connected between this pin and analog ground (AGND).
36	PDWN	Power-Down Function Select.
38	CLK+	Clock Input (+).
39	CLK-	Clock Input (–).
43	OEB	Output Enable (Active Low).
44	DCO	Data Clock Output.

EQUIVALENT CIRCUITS

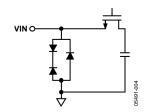


Figure 4. Equivalent Analog Input Circuit

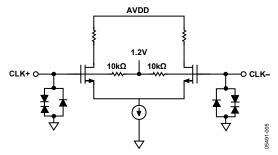


Figure 5. Equivalent Clock Input Circuit

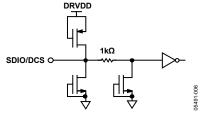


Figure 6. Equivalent SDIO/DCS Input Circuit

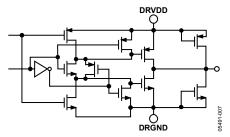


Figure 7. Equivalent Digital Output Circuit

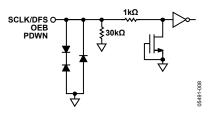


Figure 8. Equivalent SCLK/DFS, OEB, PDWN Input Circuit

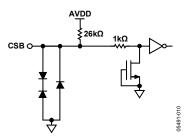


Figure 9. Equivalent CSB Input Circuit

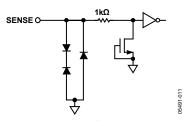


Figure 10. Equivalent Sense Circuit

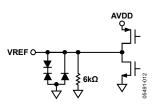


Figure 11. Equivalent VREF Circuit

TYPICAL PERFORMANCE CHARACTERISTICS

AVDD = 1.8 V; DRVDD = 2.5 V; maximum sample rate, DCS enabled, 1 V internal reference; 2 V p-p differential input; AIN = -1.0 dBFS; 64k sample; $T_A = 25$ °C, unless otherwise noted. All figures show typical performance for all speed grades.

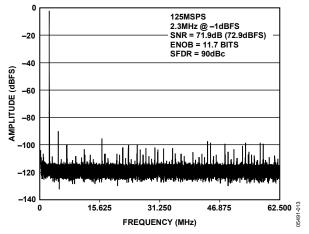


Figure 12. AD9246-125 Single-Tone FFT with $f_{IN} = 2.3$ MHz

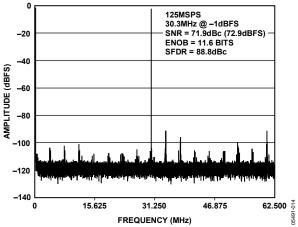


Figure 13. AD9246-125 Single-Tone FFT with $f_{IN} = 30.3$ MHz

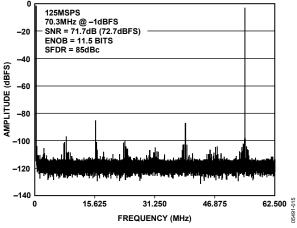


Figure 14. AD9246-125 Single-Tone FFT with $f_{IN} = 70.3$ MHz

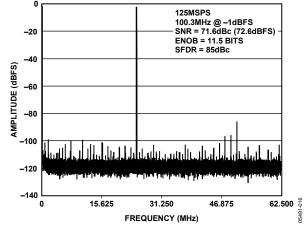


Figure 15. AD9246-125 Single-Tone FFT with $f_{IN} = 100.3$ MHz

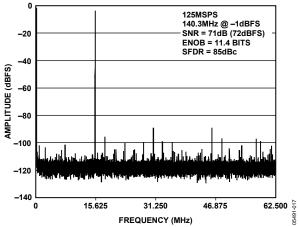


Figure 16. AD9246-125 Single-Tone FFT with f_{IN} = 140.3 MHz

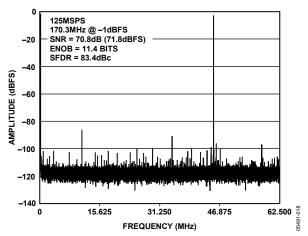


Figure 17. AD9246-125 Single-Tone FFT with $f_{IN} = 170.3$ MHz

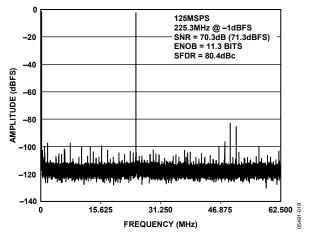


Figure 18. AD9246-125 Single-Tone FFT with f_{IN} = 225.3 MHz

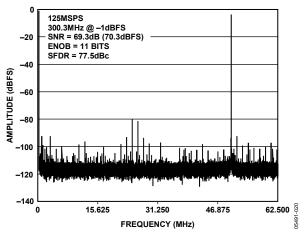


Figure 19. AD9246-125 Single-Tone FFT with f_{IN} = 300.3 MHz

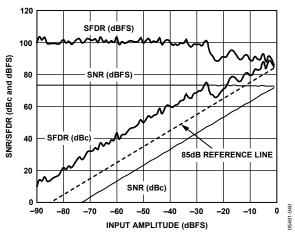


Figure 20. AD9246 Single-Tone SNR/SFDR vs. Input Amplitude (AIN) with $f_{\rm IN}$ = 2.4 MHz

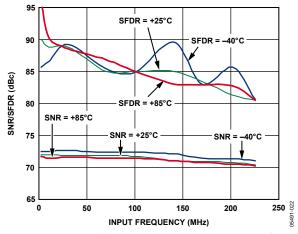


Figure 21. AD9246 Single-Tone SNR/SFDR vs. Input Frequency (f_{IN}) and Temperature with 2 V p-p Full Scale

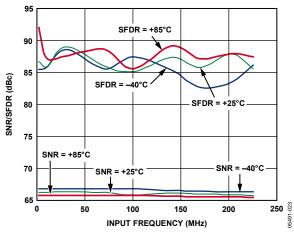


Figure 22. AD9246 Single-Tone SNR/SFDR vs. Input Frequency (f_{IN}) and Temperature with 1 V p-p Full Scale

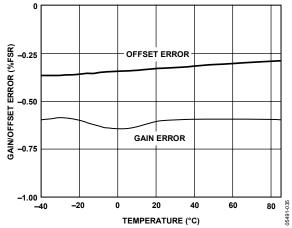


Figure 23. AD9246 Gain and Offset vs. Temperature

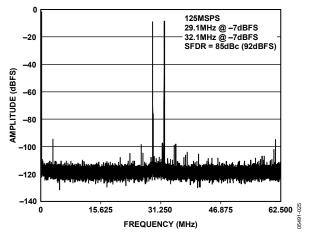


Figure 24. AD9246-125 Two-Tone FFT with $f_{IN1} = 29.1$ MHz, $f_{IN2} = 32.1$ MHz

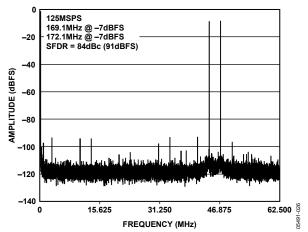


Figure 25. AD9246-125 Two-Tone FFT with $f_{IN1} = 169.1$ MHz, $f_{IN2} = 172.1$ MHz

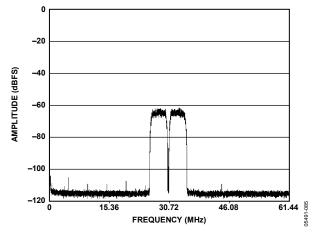


Figure 26. AD9246-125 Two 64k WCDMA Carriers with $f_{IN} = 215.04$ MHz, $f_{S} = 122.88$ MSPS

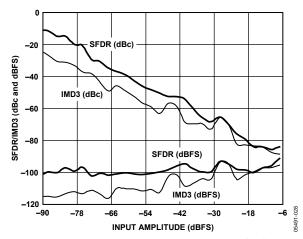


Figure 27. AD9246 Two-Tone SFDR/IMD vs. Input Amplitude (AIN) with $F_{IN1} = 29.1$ MHz, $F_{IN2} = 32.1$ MHz

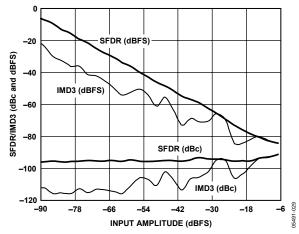


Figure 28. AD9246 Two-Tone SFDR/IMD vs. Input Amplitude (AIN) with $F_{IN1} = 169.1 \text{ MHz}$, $F_{IN2} = 172.11 \text{ MHz}$

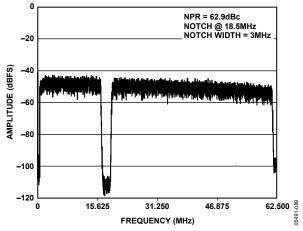


Figure 29. AD9246 Noise Power Ratio (NPR)

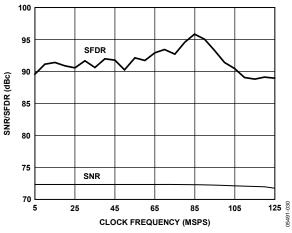


Figure 30. AD9246 Single-Tone SNR/SFDR vs. Clock Frequency (f_s) with $f_{\rm IN}$ = 2.4 MHz

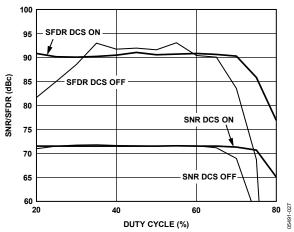


Figure 31. AD9246 SNR/SFDR vs. Duty Cycle with $f_{\text{IN}} = 10.3 \text{ MHz}$

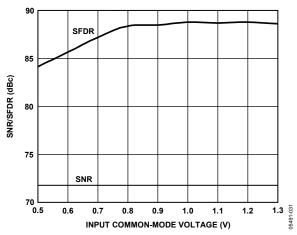


Figure 32. AD9246 SNR/SFDR vs. Input Common Mode (VCM) with $f_{\rm IN}=30$ MHz

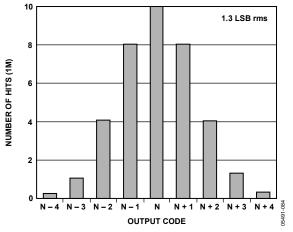


Figure 33. AD9246 Grounded Input Histogram

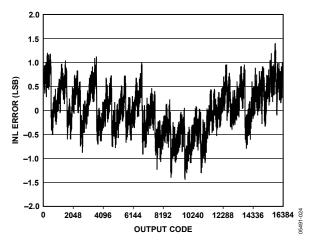


Figure 34. AD9246 INL with $f_{IN} = 10.3 MHz$

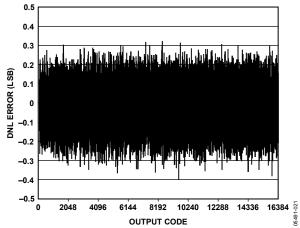


Figure 35. AD9246 DNL with $f_{IN} = 10.3 \text{ MHz}$

THEORY OF OPERATION

The AD9246 architecture consists of a front-end sample-and-hold amplifier (SHA) followed by a pipelined switched capacitor ADC. The quantized outputs from each stage are combined into a final 14-bit result in the digital correction logic. The pipeline architecture permits the first stage to operate on a new input sample, while the remaining stages operate on preceding samples. Sampling occurs on the rising edge of the clock.

Each stage of the pipeline, excluding the last, consists of a low resolution flash ADC connected to a switched capacitor DAC and interstage residue amplifier (MDAC). The residue amplifier magnifies the difference between the reconstructed DAC output and the flash input for the next stage in the pipeline. One bit of redundancy is used in each stage to facilitate digital correction of flash errors. The last stage simply consists of a flash ADC.

The input stage contains a differential SHA that can be ac- or dc-coupled in differential or single-ended modes. The output staging block aligns the data, carries out the error correction, and passes the data to the output buffers. The output buffers are powered from a separate supply, allowing adjustment of the output voltage swing. During power down, the output buffers go into a high impedance state.

ANALOG INPUT CONSIDERATIONS

The analog input to the AD9246 is a differential switched capacitor SHA that has been designed for optimum performance while processing a differential input signal.

The clock signal alternately switches the SHA between sample mode and hold mode (see Figure 36). When the SHA is switched into sample mode, the signal source must be capable of charging the sample capacitors and settling within one-half of a clock cycle. A small resistor in series with each input can help reduce the peak transient current required from the output stage of the driving source.

A shunt capacitor can be placed across the inputs to provide dynamic charging currents. This passive network creates a low-pass filter at the ADC input; therefore, the precise values are dependent on the application.

In IF undersampling applications, any shunt capacitors should be reduced. In combination with the driving source impedance, these capacitors would limit the input bandwidth. For more information, see Application Notes AN-742, Frequency Domain Response of Switched-Capacitor ADCs; and AN-827, A Resonant Approach to Interfacing Amplifiers to Switched-Capacitor ADCs, and the Analog Dialogue article, "Transformer-Coupled Front-End for Wideband A/D Converters."

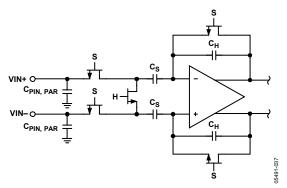


Figure 36. Switched Capacitor SHA Input

For best dynamic performance, the source impedances driving VIN+ and VIN- should match such that common-mode settling errors are symmetrical. These errors are reduced by the common-mode rejection of the ADC.

An internal differential reference buffer creates two reference voltages used to define the input span of the ADC core. The span of the ADC core is set by the buffer to be 2 \times VREF. The reference voltages are not available to the user. Two bypass points, REFT and REFB, are brought out for decoupling to reduce the noise contributed by the internal reference buffer. It is recommended that REFT be decoupled to REFB by a 0.1 μF capacitor, as described in the Layout Considerations section.

Input Common Mode

The analog inputs of the AD9246 are not internally dc-biased. In ac-coupled applications, the user must provide this bias externally. Setting the device such that $V_{\text{CM}}=0.55\times\text{AVDD}$ is recommended for optimum performance; however, the device functions over a wider range with reasonable performance (see Figure 32). An on-board, common-mode voltage reference is included in the design and is available from the CML pin. Optimum performance is achieved when the common-mode voltage of the analog input is set by the CML pin voltage (typically $0.55\times\text{AVDD}$). The CML pin must be decoupled to ground by a $0.1~\mu\text{F}$ capacitor, as described in the Layout Considerations section.

DIFFERENTIAL INPUT CONFIGURATIONS

Optimum performance is achieved by driving the AD9246 in a differential input configuration. For baseband applications, the AD8138 differential driver provides excellent performance and a flexible interface to the ADC. The output common-mode voltage of the AD8138 is easily set with the CML pin of the AD9246 (see Figure 37), and the driver can be configured in a Sallen-Key filter topology to provide band limiting of the input signal.

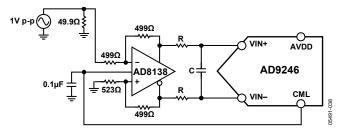


Figure 37. Differential Input Configuration Using the AD8138

For baseband applications where SNR is a key parameter, differential transformer coupling is the recommended input configuration (see Figure 38). The CML voltage can be connected to the center tap of the secondary winding of the transformer to bias the analog input.

The signal characteristics must be considered when selecting a transformer. Most RF transformers saturate at frequencies below a few MHz, and excessive signal power can cause core saturation, which leads to distortion.

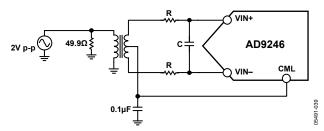


Figure 38. Differential Transformer-Coupled Configuration

At input frequencies in the second Nyquist zone and above, the noise performance of most amplifiers is not adequate to achieve the true SNR performance of the AD9246. For applications where SNR is a key parameter, transformer coupling is the recommended input.

For applications where SFDR is a key parameter, differential double balun coupling is the recommended input configuration (see Figure 40).

As an alternative to using a transformer-coupled input at frequencies in the second Nyquist zone, the AD8352 differential driver can be used (see Figure 41).

In any configuration, the value of the shunt capacitor, C, is dependent on the input frequency and source impedance and may need to be reduced or removed. Table 8 displays recommended values to set the RC network. However, these values are dependent on the input signal and should only be used as a starting guide.

Table 8. RC Network Recommended Values

Frequency Range (MHz)	R Series (Ω)	C Differential (pF)
0 to 70	33	15
70 to 200	33	5
200 to 300	15	5
>300	15	Open

Single-Ended Input Configuration

Although not recommended, it is possible to operate the AD9246 in a single-ended input configuration, as long as the input voltage swing is within the AVDD supply. Single-ended operation can provide adequate performance in cost-sensitive applications.

In this configuration, SFDR and distortion performance degrade due to the large input common-mode swing. If the source impedances on each input are matched, there should be little effect on SNR performance. Figure 39 details a typical single-ended input configuration.

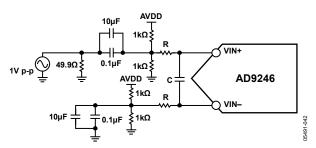


Figure 39. Single-Ended Input Configuration

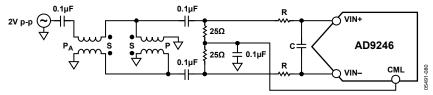


Figure 40. Differential Double Balun Input Configuration

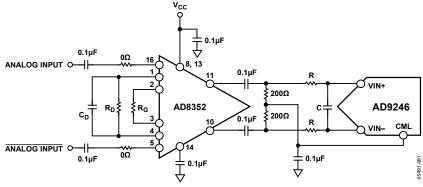


Figure 41. Differential Input Configuration Using the AD8352

Table 9. Reference Configuration Summary

Selected Mode	SENSE Voltage	Resulting VREF (V)	Resulting Differential Span (V p-p)
External Reference	AVDD	N/A	2 × External Reference
Internal Fixed Reference	VREF	0.5	1.0
Programmable Reference	0.2 V to VREF	$0.5 \times \left(1 + \frac{R2}{RI}\right)$ (see Figure 43)	2×VREF
Internal Fixed Reference	AGND to 0.2 V	1.0	2.0

VOLTAGE REFERENCE

A stable and accurate voltage reference is built into the AD9246. The input range is adjustable by varying the reference voltage applied to the AD9246, using either the internal reference or an externally applied reference voltage. The input span of the ADC tracks reference voltage changes linearly. The various reference modes are summarized in the following sections. The Reference Decoupling section describes the best practices and requirements for PCB layout of the reference.

Internal Reference Connection

A comparator within the AD9246 detects the potential at the SENSE pin and configures the reference into four possible states, as summarized in Table 9. If SENSE is grounded, the reference amplifier switch is connected to the internal resistor divider (see Figure 42), setting VREF to 1 V.

Connecting the SENSE pin to VREF switches the reference amplifier input to the SENSE pin, completing the loop and providing a 0.5 V reference output.

If a resistor divider is connected external to the chip as shown in Figure 43, the switch sets to the SENSE pin. This puts the reference amplifier in a noninverting mode with the VREF output defined as

$$VREF = 0.5 \left(1 + \frac{R2}{R1} \right)$$

If the SENSE pin is connected to AVDD, the reference amplifier is disabled, and an external reference voltage can be applied to the VREF pin (see the External Reference Operation section).

The input range of the ADC always equals twice the voltage at the reference pin for either an internal or an external reference.

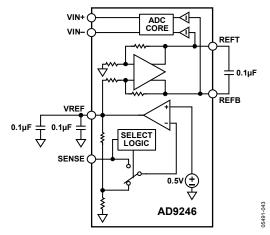


Figure 42. Internal Reference Configuration

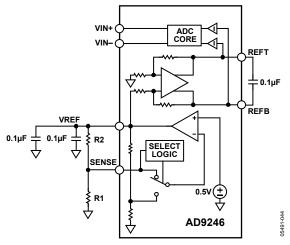


Figure 43. Programmable Reference Configuration

If the internal reference of the AD9246 is used to drive multiple converters to improve gain matching, the loading of the reference by the other converters must be considered. Figure 44 depicts how the internal reference voltage is affected by loading.

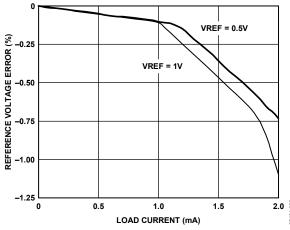


Figure 44. VREF Accuracy vs. Load

External Reference Operation

The use of an external reference may be necessary to enhance the gain accuracy of the ADC or improve thermal drift characteristics. Figure 45 shows the typical drift characteristics of the internal reference in both 1 V and 0.5 V modes.

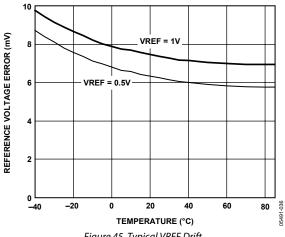


Figure 45. Typical VREF Drift

When the SENSE pin is tied to AVDD, the internal reference is disabled, allowing the use of an external reference. An internal resistor divider loads the external reference with an equivalent 6 k Ω load (see Figure 11). In addition, an internal buffer generates the positive and negative full-scale references for the ADC core. Therefore, the external reference must be limited to a maximum of 1 V.

CLOCK INPUT CONSIDERATIONS

For optimum performance, the AD9246 sample clock inputs (CLK+ and CLK-) should be clocked with a differential signal. The signal is typically ac-coupled into the CLK+ pin and the CLK- pin via a transformer or capacitors. These pins are biased internally (see Figure 5) and require no external bias.

Clock Input Options

The AD9246 has a very flexible clock input structure. The clock input can be a CMOS, LVDS, LVPECL, or sine wave signal. Regardless of the type of signal used, the jitter of the clock source is of the most concern (see the Jitter Considerations section).

Figure 46 shows one preferred method for clocking the AD9246. A low jitter clock source is converted from single-ended to a differential signal using an RF transformer. The back-to-back Schottky diodes across the transformer secondary limit clock excursions into the AD9246 to approximately 0.8 V p-p differential. This helps prevent the large voltage swings of the clock from feeding through to other portions of the AD9246, while preserving the fast rise and fall times of the signal, which are critical to a low jitter performance.

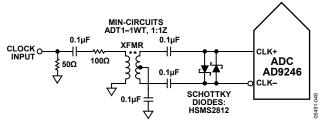


Figure 46. Transformer Coupled Differential Clock

If a low jitter clock source is not available, another option is to ac-couple a differential PECL signal to the sample clock input pins, as shown in Figure 47. The AD9510/AD9511/AD9512/AD9513/AD9514/AD9515 family of clock drivers offers excellent jitter performance.

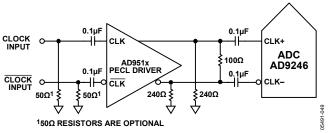


Figure 47. Differential PECL Sample Clock

A third option is to ac-couple a differential LVDS signal to the sample clock input pins, as shown in Figure 48. The AD9510/AD9511/AD9512/AD9513/AD9514/AD9515 family of clock drivers offers excellent jitter performance.

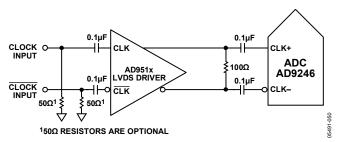


Figure 48. Differential LVDS Sample Clock

In some applications, it is acceptable to drive the sample clock inputs with a single-ended CMOS signal. In such applications, directly drive CLK+ from a CMOS gate, while bypassing the CLK– pin to ground using a 0.1 μF capacitor in parallel with a 39 k Ω resistor (see Figure 49). CLK+ may be directly driven from a CMOS gate. This input is designed to withstand input voltages up to 3.6 V, making the selection of the drive logic voltage very flexible. When driving CLK+ with a 1.8 V CMOS signal, biasing the CLK– pin with a 0.1 μF capacitor in parallel with a 39 k Ω resistor (see Figure 49) is required. The 39 k Ω resistor is not required when driving CLK+ with a 3.3 V CMOS signal (see Figure 50).

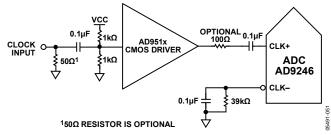


Figure 49. Single-Ended 1.8 V CMOS Sample Clock

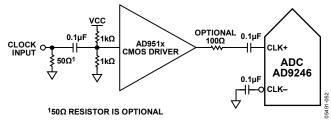


Figure 50. Single-Ended 3.3 V CMOS Sample Clock

Clock Duty Cycle

Typical high speed ADCs use both clock edges to generate a variety of internal timing signals. As a result, these ADCs may be sensitive to clock duty cycle. Commonly, a ±5% tolerance is required on the clock duty cycle to maintain dynamic performance characteristics.

The AD9246 contains a duty cycle stabilizer (DCS) that retimes the nonsampling, or falling edge, providing an internal clock signal with a nominal 50% duty cycle. This allows a wide range of clock input duty cycles without affecting the performance of the AD9246. Noise and distortion performance are nearly flat for a wide range of duty cycles when the DCS is on, as shown in Figure 31.

Jitter in the rising edge of the input is still of paramount concern and is not reduced by the internal stabilization circuit. The duty cycle control loop does not function for clock rates less than 20 MHz nominally. The loop has a time constant associated with it that needs to be considered in applications where the clock rate can change dynamically. This requires a wait time of 1.5 μs to 5 μs after a dynamic clock frequency increase (or decrease) before the DCS loop is relocked to the input signal. During the time period the loop is not locked, the DCS loop is bypassed, and the internal device timing is dependent on the duty cycle of the input clock signal. In such an application, it may be appropriate to disable the duty cycle stabilizer. In all other applications, enabling the DCS circuit is recommended to maximize ac performance.

The DCS can be enabled or disabled by setting the SDIO/DCS pin when operating in the external pin mode (see Table 10), or via the SPI, as described in Table 13.

Table 10. Mode Selection (External Pin Mode)

Voltage at Pin	SCLK/DFS	SDIO/DCS
AGND	Binary (default)	DCS disabled
AVDD	Twos complement	DCS enabled (default)

JITTER CONSIDERATIONS

High speed, high resolution ADCs are sensitive to the quality of the clock input. The degradation in SNR at a given input frequency $(f_{\rm IN})$ due to jitter $(t_{\rm J})$ is calculated as follows:

$$SNR = -20 \log (2\pi \times f_{IN} \times t_J)$$

In the equation, the rms aperture jitter represents the root mean square of all jitter sources, which include the clock input, analog input signal, and ADC aperture jitter specification. IF undersampling applications are particularly sensitive to jitter, as illustrated in Figure 51.

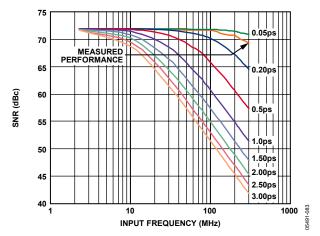


Figure 51. SNR vs. Input Frequency and Jitter

Treat the clock input as an analog signal in cases where aperture jitter may affect the dynamic range of the AD9246. Power supplies for clock drivers should be separated from the ADC output driver supplies to avoid modulating the clock signal with digital noise. The power supplies should also not be shared with analog input circuits, such as buffers, to avoid the clock modulating onto the input signal or vice versa. Low jitter, crystal-controlled oscillators make the best clock sources. If the clock is generated from another type of source (by gating, dividing, or other methods), it should be retimed by the original clock at the last step.

Refer to Application Notes AN-501, Aperture Uncertainty and ADC System Performance, and AN-756, Sampled Systems and the Effects of Clock Phase Noise and Jitter, for more in-depth information about jitter performance as it relates to ADCs.

POWER DISSIPATION AND STANDBY MODE

As shown in Figure 52 and Figure 53, the power dissipated by the AD9246 is proportional to its sample rate. The digital power dissipation is determined primarily by the strength of the digital drivers and the load on each output bit. The maximum DRVDD current (I_{DRVDD}) can be calculated as:

$$I_{DRVDD} = V_{DRVDD} \times C_{LOAD} \times \frac{f_{CLK}}{2} \times N$$

where N is the number of output bits, 14 in the case of the AD9246.

This maximum current occurs when every output bit switches on every clock cycle, that is, a full-scale square wave at the Nyquist frequency, $f_{\rm CLK}/2$. In practice, the DRVDD current is established by the average number of output bits switching, which is determined by the sample rate and the characteristics of the analog input signal. Reducing the capacitive load presented to the output drivers can minimize digital power consumption. The data in Figure 52 and Figure 53 was taken under the same operating conditions as the data for the Typical Performance Characteristics section, with a 5 pF load on each output driver.

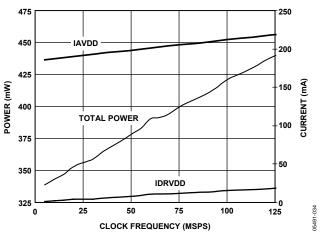


Figure 52. AD9246-125 Power and Current vs. Clock Frequency $f_{IN} = 30 \text{ MHz}$

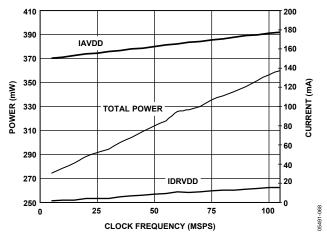


Figure 53. AD9246-105 Power and Current vs. Clock Frequency $f_{IN} = 30 \text{ MHz}$

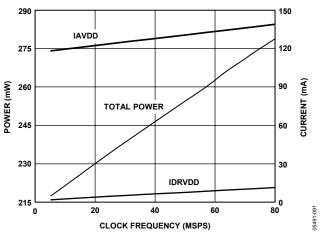


Figure 54. AD9246-80 Power and Current vs. Clock Frequency $f_{IN} = 30 \text{ MHz}$

Power-Down Mode

By asserting the PDWN pin high, the AD9246 is placed in power-down mode. In this state, the ADC typically dissipates 1.8 mW. During power-down, the output drivers are placed in a high impedance state. Reasserting the PDWN pin low returns the AD9246 to its normal operational mode. This pin is both 1.8 V and 3.3 V tolerant.

Low power dissipation in power-down mode is achieved by shutting down the reference, reference buffer, biasing networks, and clock. The decoupling capacitors on REFT and REFB are discharged when entering power-down mode and then must be recharged when returning to normal operation. As a result, the wake-up time is related to the time spent in power-down mode; and shorter power-down cycles result in proportionally shorter wake-up times. With the recommended 0.1 μF decoupling capacitors on REFT and REFB, it takes approximately 0.25 ms to fully discharge the reference buffer decoupling capacitors and 0.35 ms to restore full operation.

Standby Mode

When using the SPI port interface, the user can place the ADC in power-down mode or standby mode. Standby mode allows the user to keep the internal reference circuitry powered when faster wake-up times are required (see the Memory Map section).

DIGITAL OUTPUTS

The AD9246 output drivers can be configured to interface with 1.8 V to 3.3 V logic families by matching DRVDD to the digital supply of the interfaced logic. The output drivers are sized to provide sufficient output current to drive a wide variety of logic families. However, large drive currents tend to cause current glitches on the supplies that may affect converter performance. Applications requiring the ADC to drive large capacitive loads or large fan-outs may require external buffers or latches.

The output data format can be selected for either offset binary or twos complement by setting the SCLK/DFS pin when operating in the external pin mode (see Table 10).

As detailed in the *Interfacing to High Speed ADCs via SPI* User Manual, the data format can be selected for either offset binary, twos complement, or Gray code when using the SPI control.

Out-of-Range (OR) Condition

An out-of-range condition exists when the analog input voltage is beyond the input range of the ADC. OR is a digital output that is updated along with the data output corresponding to the particular sampled input voltage. Thus, OR has the same pipeline latency as the digital data.

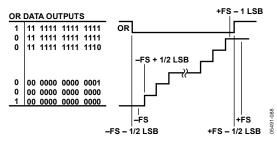


Figure 55. OR Relation to Input Voltage and Output Data

OR is low when the analog input voltage is within the analog input range and high when the analog input voltage exceeds the input range, as shown in Figure 55. OR remains high until the analog input returns to within the input range, and another conversion is completed. By logically AND'ing the OR bit with the MSB and its complement, overrange high or underrange low conditions can be detected. Table 11 is a truth table for the overrange/ underrange circuit in Figure 56, which uses NAND gates.

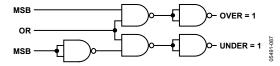


Figure 56. Overrange/Underrange Logic

Table 11. Overrange/Underrange Truth Table

OR	MSB	Analog Input Is:
0	0	Within range
0	1	Within range
1	0	Underrange
1	1	Overrange

Digital Output Enable Function (OEB)

The AD9246 has three-state ability. If the OEB pin is low, the output data drivers are enabled. If the OEB pin is high, the output data drivers are placed in a high impedance state. This is not intended for rapid access to the data bus. Note that OEB is referenced to the digital supplies (DRVDD) and should not exceed that supply voltage.

TIMING

The lowest typical conversion rate of the AD9246 is 10 MSPS. At clock rates below 10 MSPS, dynamic performance can degrade.

The AD9246 provides latched data outputs with a pipeline delay of 12 clock cycles. Data outputs are available one propagation delay (tpd) after the rising edge of the clock signal.

The length of the output data lines and the loads placed on them should be minimized to reduce transients within the AD9246. These transients can degrade the dynamic performance of the converter.

Data Clock Output (DCO)

The AD9246 provides a data clock output (DCO) intended for capturing the data in an external register. The data outputs are valid on the rising edge of DCO, unless the DCO clock polarity has been changed via the SPI. See Figure 2 for a graphical timing description.

Table 12. Output Data Format

Input (V)	Condition (V)	Binary Output Mode	Twos Complement Mode	Gray Code Mode (SPI accessible)	OR
VIN+ - VIN-	< -VREF - 0.5 LSB	00 0000 0000 0000	10 0000 0000 0000	11 0000 0000 0000	1
VIN+ - VIN-	= -VREF	00 0000 0000 0000	10 0000 0000 0000	11 0000 0000 0000	0
VIN+ - VIN-	= 0	10 0000 0000 0000	00 0000 0000 0000	00 0000 0000 0000	0
VIN+ - VIN-	= +VREF - 1.0 LSB	11 1111 1111 1111	01 1111 1111 1111	10 0000 0000 0000	0
VIN+ - VIN-	> +VREF – 0.5 LSB	11 1111 1111 1111	01 1111 1111 1111	10 0000 0000 0000	1

SERIAL PORT INTERFACE (SPI)

The AD9246 serial port interface (SPI) allows the user to configure the converter for specific functions or operations through a structured register space provided inside the ADC. This provides the user added flexibility and customization, depending on the application. Addresses are accessed via the serial port and can be written to or read from via the port. Memory is organized into bytes that are further divided into fields, as documented in the Memory Map section. For detailed operational information, see the *Interfacing to High Speed ADCs via SPI* User Manual.

CONFIGURATION USING THE SPI

As summarized in Table 13, three pins define the SPI of this ADC. The SCLK/DFS pin synchronizes the read and write data presented to the ADC. The SDIO/DCS dual purpose pin allows data to be sent and read from the internal ADC memory map registers. The CSB pin is an active low control that enables or disables the read and write cycles.

Table 13. Serial Port Interface Pins

Pin Name	Function
SCLK/DFS	SCLK (serial clock) is the serial shift clock in. SCLK synchronizes serial interface reads and writes.
SDIO/DCS	SDIO (serial data input/output) is a dual purpose
	pin. The typical role for this pin is an input and output, depending on the instruction being sent
	and the relative position in the timing frame.
CSB	CSB (chip select bar) is an active low control that gates the read and write cycles.

The falling edge of the CSB, in conjunction with the rising edge of the SCLK, determines the start of the framing. Figure 57 and Table 14 provide examples of the serial timing and its definitions.

Other modes involving the CSB are available. The CSB can be held low indefinitely to permanently enable the device (this is called streaming). The CSB can stall high between bytes to allow for additional external timing. When CSB is tied high, SPI functions are placed in a high impedance mode. This mode turns on any SPI pin secondary functions.

During an instruction phase, a 16-bit instruction is transmitted. Data follows the instruction phase, and the length is determined by the W0 bit and the W1 bit. All data is composed of 8-bit words. The first bit of each individual byte of serial data indicates whether a read or write command is issued. This allows the serial data input/output (SDIO) pin to change direction from an input to an output.

In addition to word length, the instruction phase determines if the serial frame is a read or write operation, allowing the serial port to be used to both program the chip as well as read the contents of the on-chip memory. If the instruction is a readback operation, performing a readback causes the serial data input/output (SDIO) pin to change direction from an input to an output at the appropriate point in the serial frame.

Data can be sent in MSB- or in LSB-first mode. MSB first is the default on power up and can be changed via the configuration register. For more information, see the *Interfacing to High Speed ADCs via SPI* User Manual.

Table 14. SPI Timing Diagram Specifications

Name	Description
t _{DS}	Setup time between data and rising edge of SCLK
t_{DH}	Hold time between data and rising edge of SCLK
t_{CLK}	Period of the clock
t_{S}	Setup time between CSB and SCLK
t _H	Hold time between CSB and SCLK
t _{HI}	Minimum period that SCLK should be in a logic high state
t _{LO}	Minimum period that SCLK should be in a logic low state

HARDWARE INTERFACE

The pins described in Table 13 comprise the physical interface between the user's programming device and the serial port of the AD9246. The SCLK and CSB pins function as inputs when using the SPI interface. The SDIO pin is bidirectional, functioning as an input during write phases and as an output during readback.

The SPI interface is flexible enough to be controlled by either PROM or PIC microcontrollers. This provides the user with the ability to use an alternate method to program the ADC. One method is described in detail in the Application Note AN-812, *Microcontroller-based Serial Port Interface Boot Circuit*.

When the SPI interface is not used, some pins serve a dual function. When strapped to AVDD or ground during device power-on, the pins are associated with a specific function.

CONFIGURATION WITHOUT THE SPI

In applications that do not interface to the SPI control registers, the SDIO/DCS and SCLK/DFS pins serve as stand-alone CMOS-compatible control pins. When the device is powered up, it is assumed that the user intends to use the pins as static control lines for the output data format and duty cycle stabilizer (see Table 10). In this mode, the CSB chip select should be connected to AVDD, which disables the serial port interface. For more information, see the *Interfacing to High Speed ADCs via SPI* User Manual.

MEMORY MAP

READING THE MEMORY MAP REGISTER TABLE

Each row in the memory map register table has eight address locations. The memory map is roughly divided into three sections: the chip configuration registers map (Address 0x00 to Address 0x02), the device index and transfer registers map (Address 0xFF), and the ADC functions map (Address 0x08 to Address 0x18).

Table 15 displays the register address number in hexadecimal in the first column. The last column displays the default value for each hexadecimal address. The Bit 7 (MSB) column is the start of the default hexadecimal value given. For example, Hexadecimal Address 0x14, output_phase, has a hexadecimal default value of 0x00. This means Bit 3=0, Bit 2=0, Bit 1=1, and Bit 0=1 or 0011 in binary. This setting is the default output clock or DCO phase adjust option. The default value adjusts the DCO phase 90° relative to the nominal DCO edge and 180° relative to the data edge. For more information on this function, consult the *Interfacing to High Speed ADCs via SPI* User Manual.

Open Locations

Locations marked as open are currently not supported for this device. When required, these locations should be written with 0s. Writing to these locations is required only when part of an address location is open (for example, Address 0x14). If the entire address location is open (Address 0x13), then the address location does not need to be written.

Default Values

Coming out of reset, critical registers are loaded with default values. The default values for the registers are shown in Table 15.

Logic Levels

An explanation of two registers follows:

- "Bit is set" is synonymous with "Bit is set to Logic 1" or "Writing Logic 1 for the bit."
- "Clear a bit" is synonymous with "Bit is set to Logic 0" or "Writing Logic 0 for the bit."

SPI-Accessible Features

A list of features accessible via the SPI and a brief description of what the user can do with these features follow. These features are described in detail in the *Interfacing to High Speed ADCs via SPI* User Manual.

- **Modes:** Set either power-down or standby mode.
- Clock: Access the DCS via the SPI.
- Offset: Digitally adjust the converter offset.
- Test I/O: Set test modes to have known data on output bits.
- **Output Mode:** Set up outputs; vary the strength of the output drivers.
- Output Phase: Set the output clock polarity.
- **VREF:** Set the reference voltage.

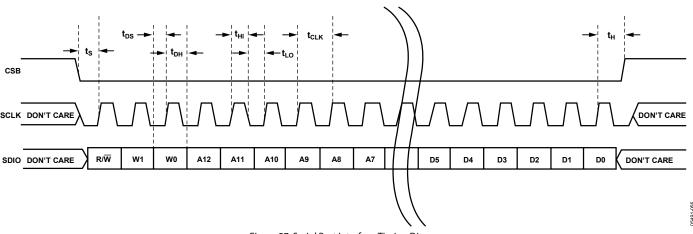


Figure 57. Serial Port Interface Timing Diagram

MEMORY MAP REGISTER TABLE

Table 15. Memory Map Register

Addr. (Hex)	Parameter Name	Bit 7 (MSB)	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0 (LSB)	Default Value (Hex)	Default Notes/ Comments
	onfiguration Regist	ers									
00	chip_port_config	0	LSB first 0 = Off (Default) 1 = On	Soft reset 0 = Off (Default) 1 = On	1	1	Soft reset 0 = Off (Default) 1 = On	LSB first 0 = Off (Default 1 = On		0x18	The nibbles should be mirrored. See the Interfacing to High Speed ADCs via SPI User Manual.
01	chip_id					hip ID Bits 7: = 0x00), (def			·	Read only	Default is unique chip ID, different for each device.
02	chip_grade	Open	Open	Open	Open	Child ID 0 = 125 MSPS, 1 = 105 MSPS	Open	Open	Open	Read only	Child ID used to differentiate speed grades.
Device	Index and Transfer	Registers									
FF	device_update	Open	Open	Open	Open	Open	Open	Open	SW transfer	0x00	Synchronously transfers data from the master shift register to the slave.
Global	ADC Functions										
08	modes	Open	Open	PDWN 0—full (Default) 1—standby	Open	Open	000—no 001—full 010—sta 011—no Note: Ext this settir	l power-do ndby rmal (powe ernal PDW ng.	er-up, Default) wn er-up) N pin overrides	0x00	Determines various generic modes of chip operation. See the Power Dissipation and Standby Mode section and the SPI- Accessible Features section.
09	clock	Open	Open	Open	Open	Open	Open	Open	Duty cycle stabilizer 0—disabled 1— enabled (Default)	0x01	See the Clock Duty Cycle section and the SPI-Accessible Features section.

Addr. (Hex)	Parameter Name	Bit 7 (MSB)	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0 (LSB)	Default Value (Hex)	Default Notes/ Comments
Flexibl	e ADC Functions		•	•			•	•			
10	offset			Digital Of 011111 011110 011101	fset Adjust	<5:0>	Offset in +31 +30 +29	LSBs		0x00	Adjustable for offset inherent in the converter. See the SPI-Accessible
				000010 000001 000000 111111 111110			+2 +1 0 (Defaul 1 -2 -3	t)			Features section.
				 100001 100000			-31 -32				
0D	test_io			PN23 0 = normal (Default) 1 = reset	PN9 0 = normal (Default) 1 = reset		000—off (001—mid 010—+FS 011——FS 100—ched 101—PN 2	scale short short short cker board o 23 sequence	utput	0x00	See the Interfacing to High Speed ADCs via SPI User Manual.
14	output_mode	Output Driver Configuration 00 for DRVDD = 3.3 V (Default) 10 for DRVDD =		Open	Output Disable 1— disabled 0— enabled 1	Open	Output Data Invert 1 = invert	Data Form 00—offse (default) 01—twos complements	t binary ent	0x00	Configures the outputs and the format of the data.
16	output_phase	Output Clock Polarity 1 = inverted 0 = normal (Default)	Open	Open	Open	Open	Open	Open	Open	0x00	See the SPI- Accessible Features section.
18	VREF	Internal Refere Resistor Divide 00—VREF = 1.2 01—VREF = 1.5 10—VREF = 1.7 11—VREF = 2.0 (Default)	r 5 V 5 V	Open	Open	Open	Open	Open	Open	0xC0	See the SPI- Accessible Features section.

¹ External output enable (OEB) pin must be high.

LAYOUT CONSIDERATIONS

POWER AND GROUND RECOMMENDATIONS

When connecting power to the AD9246, it is recommended that two separate supplies be used: one for analog (AVDD, 1.8 V nominal) and one for digital (DRVDD, 1.8 V to 3.3 V nominal). If only a single 1.8 V supply is available, it is routed to AVDD first, then tapped off and isolated with a ferrite bead or filter choke with decoupling capacitors proceeding connection to DRVDD. The user can employ several different decoupling capacitors to cover both high and low frequencies. These should be located close to the point of entry at the PC board level and close to the parts with minimal trace length.

A single PC board ground plane is sufficient when using the AD9246. With proper decoupling and smart partitioning of analog, digital, and clock sections of the PC board, optimum performance is easily achieved.

Exposed Paddle Thermal Heat Slug Recommendations

It is required that the exposed paddle on the underside of the ADC be connected to analog ground (AGND) to achieve the best electrical and thermal performance of the AD9246. An exposed, continuous copper plane on the PCB should mate to the AD9246 exposed paddle, Pin 0. The copper plane should have several vias to achieve the lowest possible resistive thermal path for heat dissipation to flow through the bottom of the PCB. These vias should be solder-filled or plugged.

To maximize the coverage and adhesion between the ADC and PCB, partition the continuous plane by overlaying a silkscreen on the PCB into several uniform sections. This provides several tie points between the two during the reflow process. Using one continuous plane with no partitions guarantees only one tie point between the ADC and PCB. See Figure 58 for a PCB layout example. For detailed information on packaging and the PCB layout of chip scale packages, see Application Note AN-772, A Design and Manufacturing Guide for the Lead Frame Chip Scale Package.

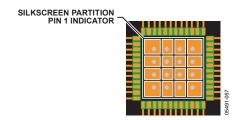


Figure 58. Typical PCB Layout

CML

The CML pin should be decoupled to ground with a 0.1 μ F capacitor, as shown in Figure 38.

RBIAS

The AD9246 requires the user to place a $10~k\Omega$ resistor between the RBIAS pin and ground. This resistor sets the master current reference of the ADC core and should have at least a 1% tolerance.

REFERENCE DECOUPLING

The VREF pin should be externally decoupled to ground with a low ESR 1.0 μF capacitor in parallel with a 0.1 μF ceramic low ESR capacitor. In all reference configurations, REFT and REFB are bypass points provided for reducing the noise contributed by the internal reference buffer. It is recommended that an external 0.1 μF ceramic capacitor be placed across REFT/REFB. While placement of this 0.1 μF capacitor is not required, the SNR performance degrades by approximately 0.1 dB without it. All reference decoupling capacitors should be placed as close to the ADC as possible with minimal trace lengths.

EVALUATION BOARD

The AD9246 evaluation board provides all of the support circuitry required to operate the ADC in its various modes and configurations. The converter can be driven differentially through a double balun configuration (default) or through the AD8352 differential driver. The ADC can also be driven in a single-ended fashion. Separate power pins are provided to isolate the DUT from the AD8352 drive circuitry. Each input configuration can be selected by proper connection of various components (see Figure 60 to Figure 70). Figure 59 shows the typical bench characterization setup used to evaluate the ac performance of the AD9246.

It is critical that the signal sources used for the analog input and clock have very low phase noise (<1 ps rms jitter) to realize the optimum performance of the converter. Proper filtering of the analog input signal to remove harmonics and lower the integrated or broadband noise at the input is also necessary to achieve the specified noise performance.

See Figure 60 to Figure 64 for the complete schematics and layout diagrams that demonstrate the routing and grounding techniques that should be applied at the system level.

POWER SUPPLIES

This evaluation board comes with a wall-mountable switching power supply that provides a 6 V, 2 A maximum output. Connect the supply to the rated 100 V ac to 240 V ac wall outlet at 47 Hz to 63 Hz. The other end is a 2.1 mm inner diameter jack that connects to the PCB at P500. Once on the PC board, the 6 V supply is fused and conditioned before connecting to five low dropout linear regulators that supply the proper bias to each of the various sections on the board.

When operating the evaluation board in a nondefault condition, L501, L503, L504, L508, and L509 can be removed to disconnect the switching power supply. This enables the user to individually bias each section of the board. Use P501 to connect a different supply for each section. At least one 1.8 V supply is needed with a 1 A current capability for AVDD_DUT and DRVDD_DUT; however, it is recommended that separate supplies be used for analog and digital. To operate the evaluation board using the AD8352 option, a separate 5.0 V supply (AMP_VDD) with a 1 A current capability is needed. To operate the evaluation board using the alternate SPI options, a separate 3.3 V analog supply is needed, in addition to the other supplies. The 3.3 V supply (AVDD_3.3V) should have a 1 A current capability, as well. Solder Jumpers J501, J502, and J505 allow the user to combine these supplies (see Figure 64 for more details).

INPUT SIGNALS

When connecting the clock and analog source, use clean signal generators with low phase noise, such as Rohde & Schwarz SMHU or Agilent HP8644 signal generators or the equivalent. Use 1-meter long, shielded, RG-58, 50 Ω coaxial cable for making connections to the evaluation board. Enter the desired frequency and amplitude for the ADC. Typically, most evaluation boards from Analog Devices, Inc. can accept a ~2.8 V p-p or 13 dBm sine wave input for the clock. When connecting the analog input source, it is recommended to use a multipole, narrowband, band-pass filter with 50 Ω terminations. Analog Devices uses TTE*, Allen Avionics, and K&L* types of band-pass filters. Connect the filter directly to the evaluation board, if possible.

OUTPUT SIGNALS

The parallel CMOS outputs interface directly with the Analog Devices standard single-channel FIFO data capture board (HSC-ADC-EVALB-SC). For more information on the FIFO boards and their optional settings, visit www.analog.com/FIFO.

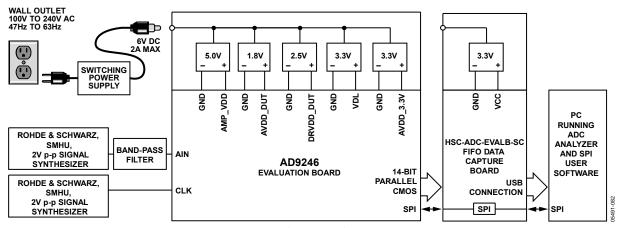


Figure 59. Evaluation Board Connection

DEFAULT OPERATION AND JUMPER SELECTION SETTINGS

The following is a list of the default and optional settings or modes allowed on the AD9246 Rev. A evaluation board.

POWER

Connect the switching power supply that is supplied in the evaluation kit between a rated 100 V ac to 240 V ac wall outlet at 47 Hz to 63 Hz and P500.

VIN

The evaluation board is set up for a double balun configuration analog input with optimum 50 Ω impedance matching out to 70 MHz. For more bandwidth response, the differential capacitor across the analog inputs can be changed or removed (see Table 8). The common mode of the analog inputs is developed from the center tap of the transformer via the CML pin of the ADC (see the Analog Input Considerations section).

VREF

VREF is set to 1.0 V by tying the SENSE pin to ground via JP507 (Pin 1 and Pin 2). This causes the ADC to operate in 2.0 V p-p full-scale range. A separate external reference option is also included on the evaluation board. Connect JP507 between Pin 2 and Pin 3, connect JP501, and provide an external reference at E500. Proper use of the VREF options is detailed in the Voltage Reference section.

RBIAS

RBIAS requires a 10 k Ω resistor (R503) to ground and is used to set the ADC core bias current.

CLOCK

The default clock input circuitry is derived from a simple transformer-coupled circuit using a high bandwidth 1:1 impedance ratio transformer (T503) that adds a very low amount of jitter to the clock path. The clock input is 50 Ω terminated and ac-coupled to handle single-ended sine wave inputs. The transformer converts the single-ended input to a differential signal that is clipped before entering the ADC clock inputs.

PDWN

To enable the power-down feature, connect JP506, shorting the PDWN pin to AVDD.

CSB

The CSB pin is internally pulled up, setting the chip into external pin mode, to ignore the SDIO and SCLK information. To connect the control of the CSB pin to the SPI circuitry on the evaluation board, connect JP1 Pin 1 and Pin 2. To set the chip into serial pin mode and enable the SPI information on the SDIO and SCLK pins, tie JP1 low (connect Pin 2 and Pin 3) in the always enabled mode.

SCLK/DFS

If the SPI port is in external pin mode, the SCLK/DFS pin sets the data format of the outputs. If the pin is left floating, the pin is internally pulled down, setting the default condition to binary. Connecting JP2 Pin 2 and Pin 3 sets the format to twos complement. If the SPI port is in serial pin mode, connecting JP2 Pin 1 and Pin 2 connects the SCLK pin to the on-board SPI circuitry (see the Serial Port Interface (SPI) section).

SDIO/DCS

If the SPI port is in external pin mode, the SDIO/DCS pin acts to set the duty cycle stabilizer. If the pin is left floating, the pin is internally pulled up, setting the default condition to DCS enabled. To disable the DCS, connect JP3 Pin 2 and Pin 3. If the SPI port is in serial pin mode, connecting JP3 Pin 1 and Pin 2 connects the SDIO pin to the on-board SPI circuitry (see the Serial Port Interface (SPI) section).

ALTERNATIVE CLOCK CONFIGURATIONS

A differential LVPECL clock can also be used to clock the ADC input using the AD9515 (U500). When using this drive option, the components listed in Table 16 need to be populated. Consult the AD9515 data sheet for more information.

To configure the analog input to drive the AD9515 instead of the default transformer option, the following components need to be added, removed, and/or changed.

- 1. Remove R507, R508, C532, and C533 in the default clock path.
- 2. Populate R505 with a 0 Ω resistor and C531 in the default clock path.
- 3. Populate R511, R512, R513, R515 to R524, U500, R580, R582, R583, R584, C536, C537, and R586.

If using an oscillator, two oscillator footprint options are also available (OSC500) to check the performance of the ADC. JP508 gives the user flexibility in using the enable pin, which is common on most oscillators. Populate OSC500, R575, R587, and R588 to use this option.

ALTERNATIVE ANALOG INPUT DRIVE CONFIGURATION

This section provides a brief description of the alternative analog input drive configuration using the AD8352. When using this particular drive option, some components need to be populated, as listed in Table 16. For more details on the AD8352 differential driver, including how it works and its optional pin settings, consult the AD8352 data sheet.

To configure the analog input to drive the AD8352 instead of the default transformer option, the following components need to be added, removed and/or changed.

- 1. Remove C1 and C2 in the default analog input path.
- 2. Populate R3 and R4 with 200 Ω resistors in the analog input path.
- 3. Populate the optional amplifier input path with all components except R594, R595, and C502. Note that to terminate the input path, only one of the following components should be populated: R9, R592, or the combination of R590 and R591.
- 4. Populate C529 with a 5 pF capacitor in the analog input path.

Currently, R561 and R562 are populated with 0 Ω resistors to allow signal connection. This area allows the user to design a filter, if additional requirements are necessary.

SCHEMATICS

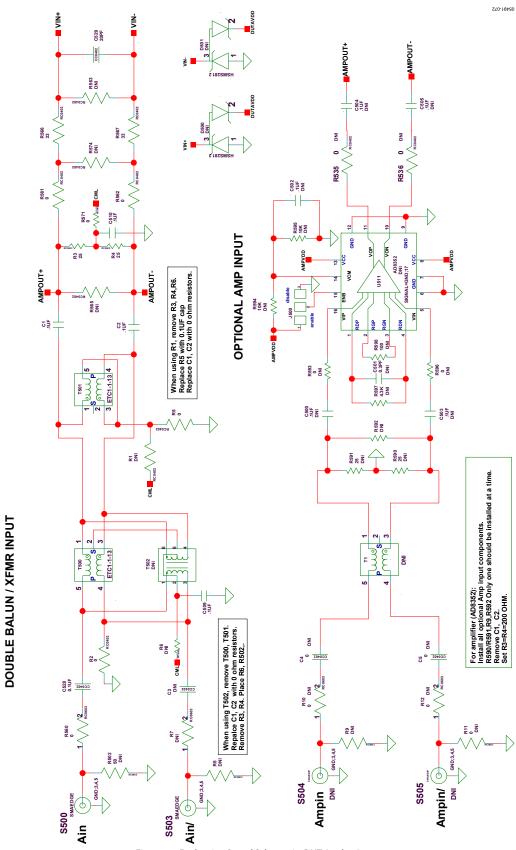


Figure 60. Evaluation Board Schematic, DUT Analog Inputs

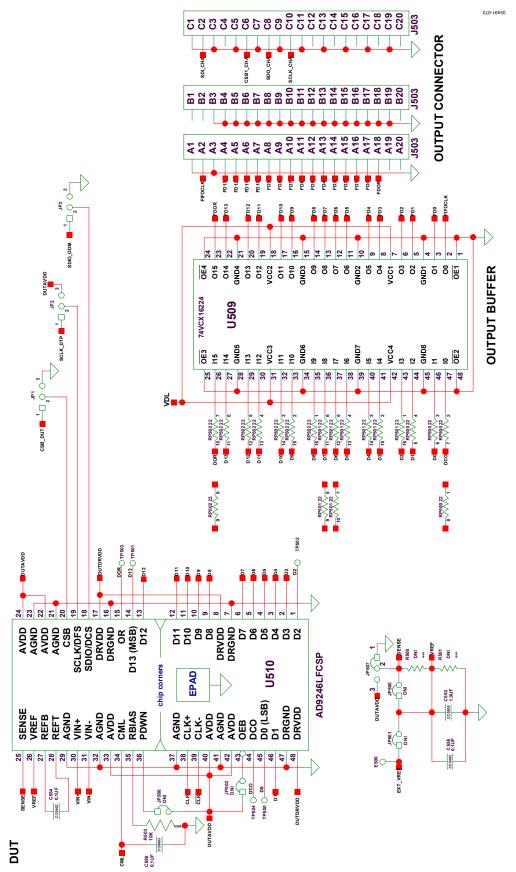
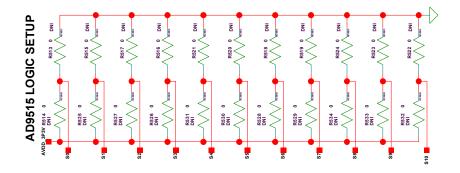


Figure 61. Evaluation Board Schematic, DUT, VREF, and Digital Output Interface

140-161/90



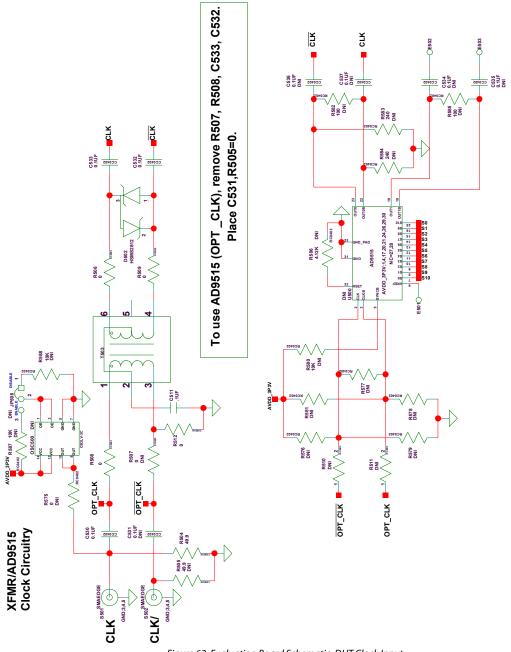


Figure 62. Evaluation Board Schematic, DUT Clock Input

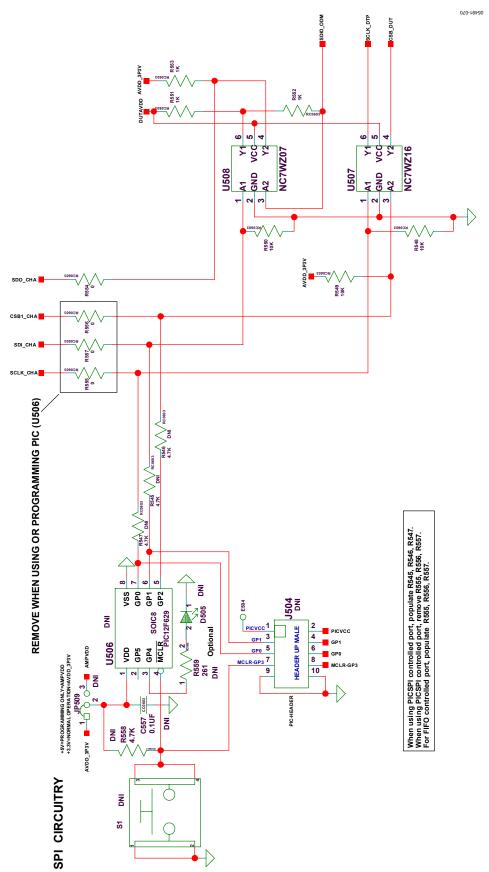


Figure 63. Evaluation Board Schematic, SPI Circuitry

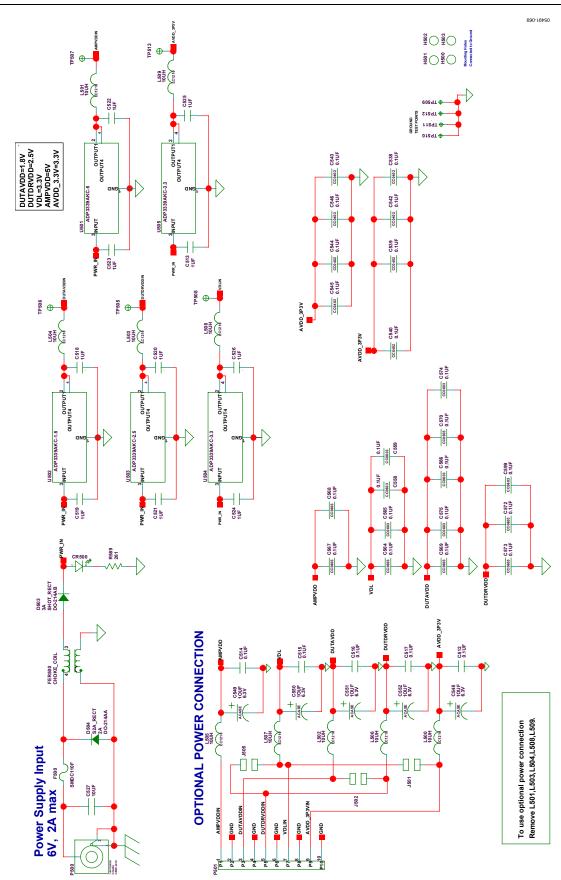


Figure 64. Evaluation Board Schematic, Power Supply Inputs

EVALUATION BOARD LAYOUTS

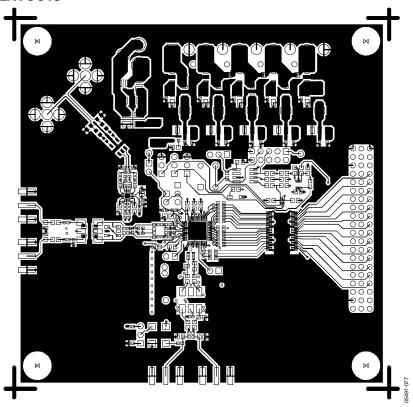


Figure 65. Evaluation Board Layout, Primary Side

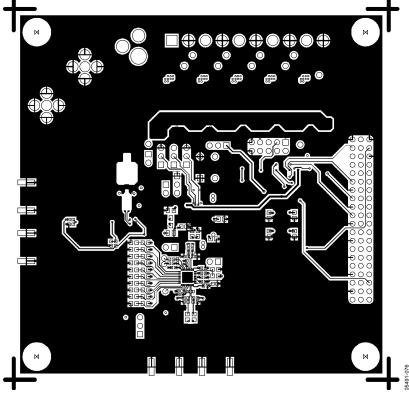


Figure 66. Evaluation Board Layout, Secondary Side (Mirrored Image)

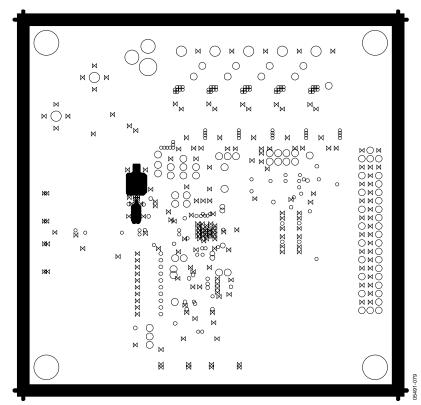


Figure 67. Evaluation Board Layout, Ground Plane

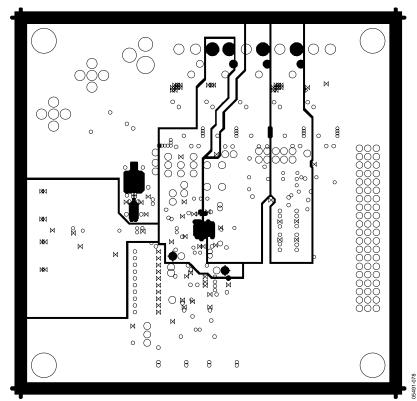


Figure 68. Evaluation Board Layout, Power Plane

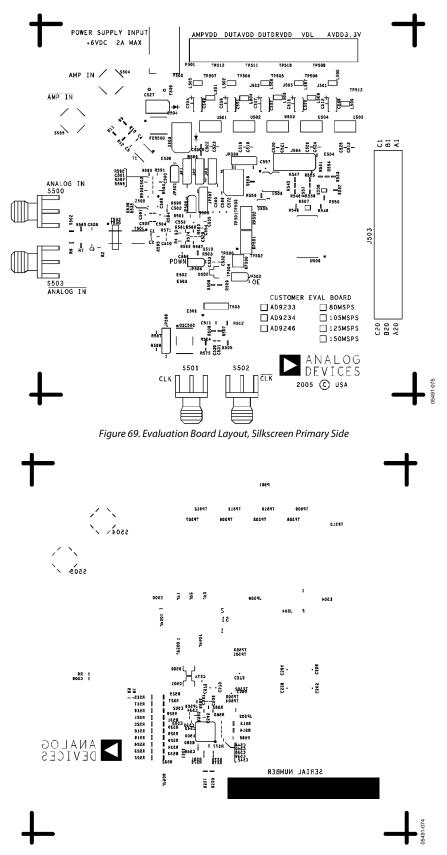


Figure 70. Evaluation Board Layout, Silkscreen Secondary Side (Mirrored Image)

BILL OF MATERIALS

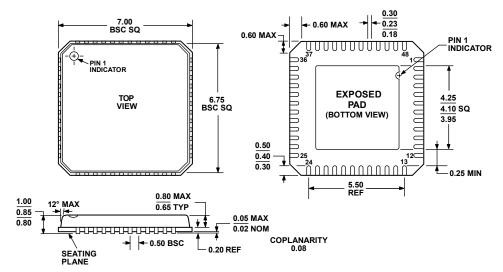
Table 16. Evaluation Board Bill of Materials (BOM)

Item	Qty.	Omit (DNP)	Reference Designator	Device	Package	Description	Supplier/Part Number
1	1	(= ::: ,	AD9246CE REVA	PCB		PCB	ADI
2	24	12	C1, C2, C509, C510, C511, C512, C514, C515, C516, C517, C528, C530, C532, C533, C538, C539, C540, C542, C543, C544, C545, C546, C554, C555 C3, C500, C502, C503, C504, C505, C531, C534, C535, C536,	Capacitor	0402	0.1 μF	
			C537, C557			_	
3		1	C501	Capacitor	0402	0.3 pF	
4	1	2	C4, C5	Resistor	0402	0 Ω	
5	10		C513, C518, C519, C520, C521, C522, C523, C524, C525, C526	Capacitor	0402	1.0 μF	
6	1		C527	Capacitor	1206	10 μF	
7	1		C529	Capacitor	0402	20 pF	
8	5		C548, C549, C550, C551, C552	Capacitor	ACASE	10 μF	
9	1		C553	Capacitor	0805	1.0 μF	
10	15		C556, C558, C559, C564, C565, C566, C567, C568, C569, C570, C572, C573, C574, C575, C599	Capacitor	0603	0.1 μF	
11	1		CR500	LED	0603	green	Panasonic LNJ314G8TRA
12	1		D502	Diode	SOT-23	30 V, 20 mA,	HSMS2812
		2	D500, D501			dual Schottky	
13	1		D503	Diode	DO-214AB	3 A, 30 V, SMC	Micro Commercial Group SK33-TPMSCT-ND
14	1		D504	Diode	DO-214AA	2 A, 50 V, SMC	Micro Commercial Group S2A-TPMSTR-ND
15		1	D505	LED	LN1461C	AMB	Amber LED
16	1		F500	Fuse	1210	6.0 V, 2.2 A trip current resettable fuse	Tyco, Raychem NANOSMDC110F-2
17	1		FER500	Choke	2020		Murata DLW5BSN191SQ2
18		1	J500	Jumper		Solder jumper	
19		3	J501, J502, J505	Jumper		Solder jumper	
20	1		J503	Connector	120 pin	Male header	Samtec TSW-140-08-G-T-RA
21		1	J504	Connector	10 pin	Male, 2 × 5	Samtec
22	3		JP1, JP2, JP3	Jumper	3 pin	Male, straight	Samtec TSW-103-07-G-S
23	4		JP500, JP501, JP502, JP506	Jumper	2 pin	Male, straight	Samtec TSW-102-07-G-S
24	1		JP507	Jumper	3-pin	Male, straight	Samtec TSW-103-07-G-S
		2	JP508, JP509		jumper		
25	10		L500, L501, L502, L503, L504, L505, L506, L507, L508, L509	Ferrite Bead	3.2 mm × 2.5 mm × 1.6 mm		Digikey P9811CT-ND
26		1	OSC500	Oscillator	SMT	125 MHz or 105 MHz	CTS Reeves CB3LV-3C
27	1		P500	Connector	PJ-102A	DC power jack	Digikey CP-102A-ND
28		1	P501	Connector	10 pin	Male, straight	PTMICRO10

ltem	Qty.	Omit (DNP)	Reference Designator	Device	Package	Description	Supplier/Part Number
29		6	R1, R6, R563, R565, R574, R577	Resistor	0402	DNI	
30	5		R2, R5, R561, R562, R571	Resistor	0402	0Ω	
		6	R10, R11, R12, R535, R536, R575				
31	2		R3, R4	Resistor	0402	25 Ω	
32		6	R7, R8, R9, R502, R510, R511	Resistor	0603	DNI	
33		6	R500, R501, R576, R578, R579, R581	Resistor	0402	DNI	
34	4		R503, R548, R549, R550	Resistor	0603	10 kΩ	
35	1		R504	Resistor	0603	49.9 Ω	
		1	R505				
36	9		R506, R508, R509, R512, R554, R555, R556, R557, R560	Resistor	0603	0 Ω	
		23	R507, R514, R513, R515, R516, R517, R518, R519, R520, R521, R522, R523, R524, R525, R526, R527, R528, R529, R530, R531, R532, R533, R534,				
37		4	R545, R546, R547, R558	Resistor	0603	4.7 kΩ	
38	3		R551, R552, R553	Resistor	0603	1 kΩ	
39		1	R559	Resistor	0603	261 Ω	
40	2		R566, R567	Resistor	0402	33 Ω	
41		3	R582, R585, R598	Resistor	0402	100 Ω	
42		2	R583, R584	Resistor	0402	240 Ω	
43		1	R586	Resistor	0402	4.12 kΩ	
44		3	R580, R587, R588	Resistor	0402	10 kΩ	
45	1		R589	Resistor	0603	261 Ω	
46		2	R590, R591	Resistor	0402	25 Ω	
47		1	R592	Resistor	0402	DNI	
48		2	R593, R596	Resistor	0402	0Ω	
49		2	R594, R595	Resistor	0402	10 kΩ	
50		1	R597	Resistor	0402	4.3 kΩ	
51	1		RP500	Resistor	RCA74204	22 Ω	
52	2		RP501, RP502	Resistor	RCA74208	22 Ω	
53		1	S1	Switch		Momentary (normally open)	Panasonic EVQ-PLDA15
54	2		S500, S501	Connector	SMAEDGE	SMA edge	
		2	S502, S503			right angle	
55		2	S504, S505	Connector	SMA200UP	SMA RF 5-pin upright	
56	2		T500, T501	Transformer	SM-22		M/A-Com ETC1-1-13
		1	T1				
57	1		T503	Transformer	CD542		Mini-Circuits ADT1-1WT
		1	T502	1		<u> </u>	
58		1	U500	IC	32-pin LFCSP	Clock distribution	ADI AD9515BCPZ
59	1		U501	IC	SOT-223	Voltage regulator	ADI ADP3339AKCZ-5
60	1		U502	IC	SOT-223	Voltage regulator	ADI ADP3339AKCZ-1.8

ltem	Qty.	Omit (DNP)	Reference Designator	Device	Package	Description	Supplier/Part Number
61	1		U503	IC	SOT-223	Voltage regulator	ADI ADP3339AKCZ-2.5
62	2		U504, U505	IC	SOT-223	Voltage regulator	ADI ADP3339AKCZ-3.3
63		1	U506	IC	8-pin SOIC	8-bit microcontroller	Microchip PIC12F629
64	1		U507	IC	SC70	Dual buffer	Fairchild NC7WZ16
65	1		U508	IC	SC70	Dual buffer	Fairchild NC7WZ07
66	1		U509	IC	48-pin TSSOP	Buffer/line driver	Fairchild 74VCX162244
67	1		U510	DUT (AD9246)	48-pin LFCSP_VQ	ADC	ADI AD9246BCPZ
68		1	U511 (or Z500)	IC	16-pin LFCSP_VQ	Differential amplifier	ADI AD8352ACPZ
Total	128	107					

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-VKKD-2

Figure 71. 48-Lead Lead Frame Chip Scale Package [LFCSP_VQ] 7 mm × 7 mm Body, Very Thin Quad (CP-48-3) Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option ¹
AD9246BCPZ-125 ²	-40°C to +85°C	48-Lead Lead Frame Chip Scale Package (LFCSP_VQ)	CP-48-3
AD9246BCPZRL7-125 ²	-40°C to +85°C	48-Lead Lead Frame Chip Scale Package (LFCSP_VQ)	CP-48-3
AD9246BCPZ-105 ²	-40°C to +85°C	48-Lead Lead Frame Chip Scale Package (LFCSP_VQ)	CP-48-3
AD9246BCPZRL7-105 ²	-40°C to +85°C	48-Lead Lead Frame Chip Scale Package (LFCSP_VQ)	CP-48-3
AD9246BCPZ-80 ²	-40°C to +85°C	48-Lead Lead Frame Chip Scale Package (LFCSP_VQ)	CP-48-3
AD9246BCPZRL7-80 ²	-40°C to +85°C	48-Lead Lead Frame Chip Scale Package (LFCSP_VQ)	CP-48-3
AD9246-125EB		Evaluation Board	
AD9246-105EB		Evaluation Board	
AD9246-80EB		Evaluation Board	

¹ It is required that the exposed paddle be soldered to the AGND plane to achieve the best electrical and thermal performance.

 $^{^{2}}$ Z = Pb-free part.

NOTES

AD9246				
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NOTES